

- **Controlled Baseline**
  - One Assembly/Test Site, One Fabrication Site
- **Extended Temperature Performance of –55°C to 125°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product Change Notification**
- **Qualification Pedigree†**
- **Output Swing Includes Both Supply Rails**

† Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

## description

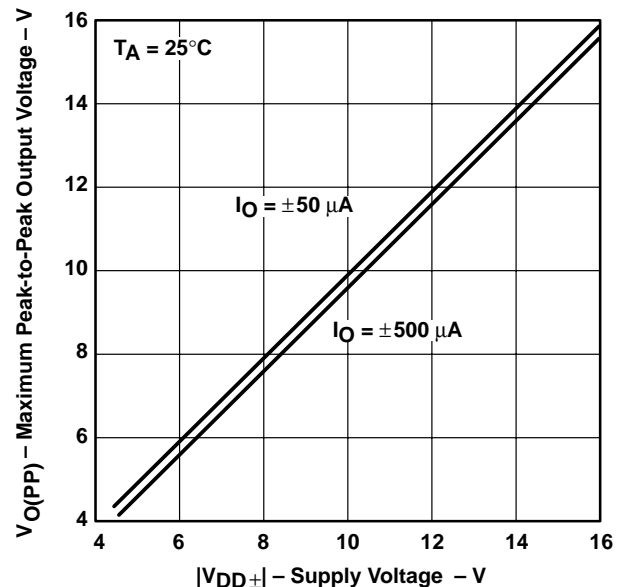
The TLC2272A and TLC2274A are dual and quadruple operational amplifiers from Texas Instruments. Both devices exhibit rail-to-rail output performance for increased dynamic range in single- or split-supply applications. The TLC227xA family offers 2 MHz of bandwidth and 3 V/μs of slew rate for higher speed applications. These devices offer comparable ac performance while having better noise, input offset voltage, and power dissipation than existing CMOS operational amplifiers. The TLC227xA has a noise voltage of 9 nV/√Hz, two times lower than competitive solutions.

The TLC227xA, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micro-power dissipation levels, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature, with single- or split-supplies, makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLC227xA family has a maximum input offset voltage of 950 μV. This family is fully characterized at 5 V and ±5 V.

The TLC2272/4 also makes great upgrades to the TLC272/4 or TS272/4 in standard designs. They offer increased output dynamic range, lower noise voltage, and lower input offset voltage. This enhanced feature set allows them to be used in a wider range of applications.

- **Low Noise . . . 9 nV/√Hz Typ at f = 1 kHz**
- **Low Input Bias Current . . . 1 pA Typ**
- **Fully Specified for Both Single-Supply and Split-Supply Operation**
- **Common-Mode Input Voltage Range Includes Negative Rail**
- **High-Gain Bandwidth . . . 2.2 MHz Typ**
- **High Slew Rate . . . 3.6 V/μs Typ**
- **Low Input Offset Voltage**  
950 μV Max at T<sub>A</sub> = 25°C
- **Macromodel Included**
- **Performance Upgrades for the TS272, TS274, TLC272, and TLC274**

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE  
vs  
SUPPLY VOLTAGE



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Advanced LinCMOS is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS  
INSTRUMENTS**

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# TLC2272A-EP TLC2274A-EP Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

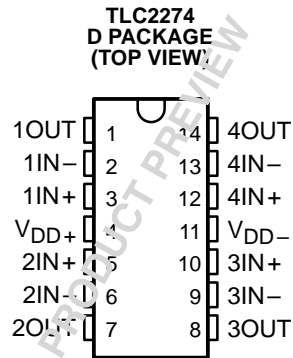
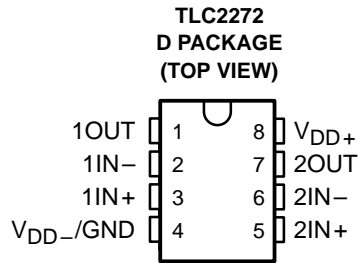
SGLS131 – JULY 2002

## ORDERING INFORMATION

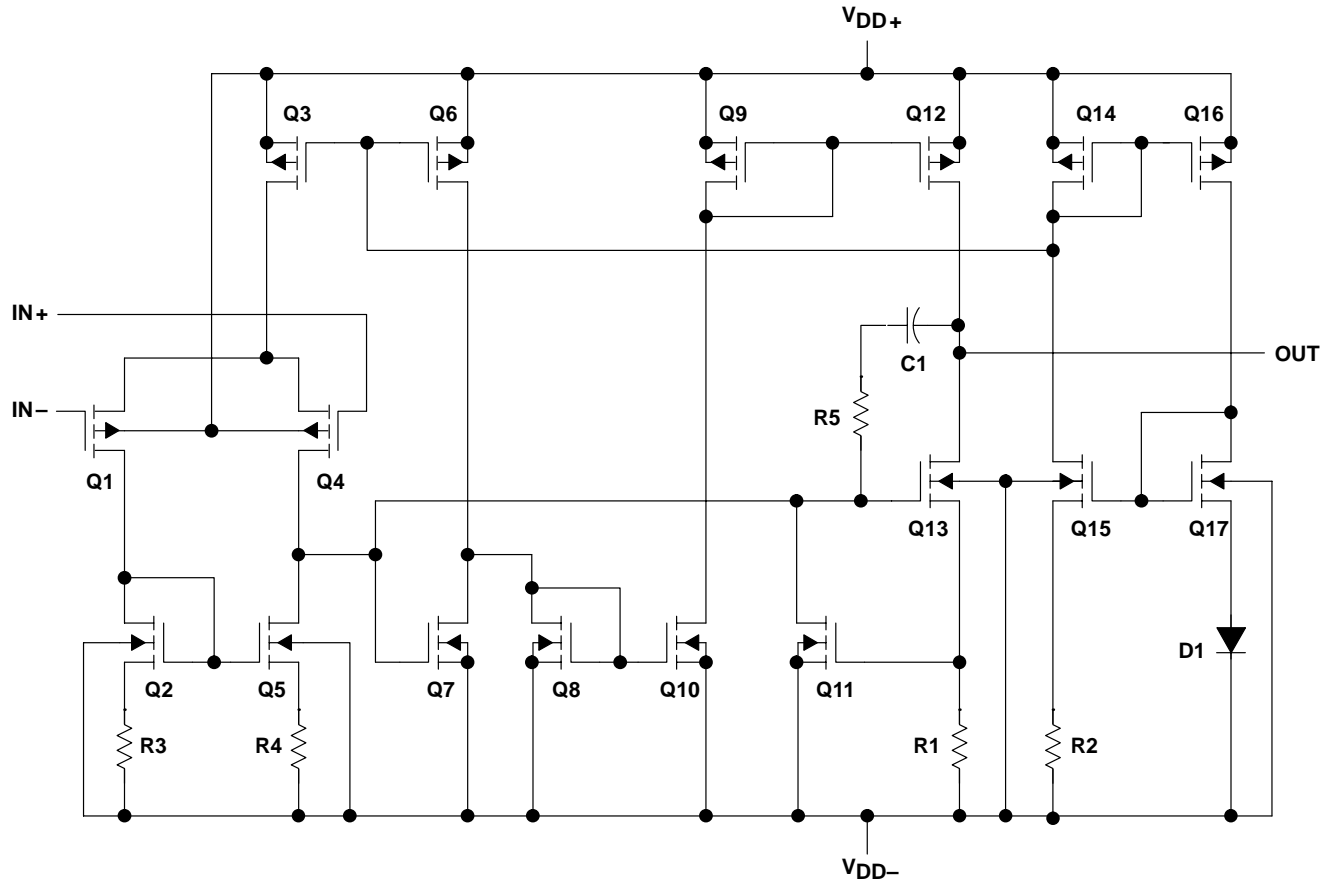
T <sub>A</sub>	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-55°C to 125°C	SOP – D	Tape and Reel	TLC2272AMDREP	2272AE

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

‡ The TLC2274A is in the **Product Preview** stage of development. Contact the local TI sales office for more information.



equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT†		
COMPONENT	TLC2272	TLC2274
Transistors	38	76
Resistors	26	52
Diodes	9	18
Capacitors	3	6

† Includes both amplifiers and all ESD, bias, and trim circuitry

# TLC2272A-EP TLC2274A-EP Advanced LinCMOS™ RAIL-TO-RAIL OPERATIONAL AMPLIFIERS

SGLS131 – JULY 2002

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{DD+}$ (see Note 1)	8 V
Supply voltage, $V_{DD-}$ (see Note 1)	-8 V
Differential input voltage, $V_{ID}$ (see Note 2)	$\pm 16$ V
Input voltage range, $V_I$ (any input, see Note 1)	$V_{DD-} - 0.3$ V to $V_{DD+}$
Input current, $I_I$ (any input)	$\pm 5$ mA
Output current, $I_O$	$\pm 50$ mA
Total current into $V_{DD+}$	$\pm 50$ mA
Total current out of $V_{DD-}$	$\pm 50$ mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$	-55°C to 125°C
Storage temperature range	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between  $V_{DD+}$  and  $V_{DD-}$ .
  2. Differential voltages are at  $IN+$  with respect to  $IN-$ . Excessive current will flow if input is brought below  $V_{DD-} - 0.3$  V.
  3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D-8	725 mW	5.8 mW/°C	464 mW	337 mW	145 mW
D-14	950 mW	7.6 mW/°C	608 mW	494 mW	190 mW

## recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, $V_{DD\pm}$	$\pm 2.2$	$\pm 8$	V
Input voltage, $V_I$	$V_{DD-}$	$V_{DD+} - 1.5$	V
Common-mode input voltage, $V_{IC}$	$V_{DD-}$	$V_{DD+} - 1.5$	V
Operating free-air temperature, $T_A$	-55	125	°C



**TLC2272A electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	$T_A$ †	MIN	TYP	MAX	UNIT	
$V_{IO}$	Input offset voltage	$V_{IC} = 0\text{ V},$ $V_{O} = 0\text{ V},$ $V_{DD\pm} = \pm 2.5\text{ V},$ $R_S = 50\ \Omega$	25°C	300	950		$\mu\text{V}$	
			Full range			1500		
$\alpha_{V_{IO}}$	Temperature coefficient of input offset voltage		25°C to 125°C	2			$\mu\text{V}/^\circ\text{C}$	
			Input offset voltage long-term drift (see Note 4)	25°C	0.002			$\mu\text{V}/\text{mo}$
$I_{IO}$	Input offset current		25°C	0.5	60		$\text{pA}$	
			Full range			800		
$I_{IB}$	Input bias current		25°C	1	60		$\text{pA}$	
			Full range			800		
$V_{ICR}$	Common-mode input voltage	$R_S = 50\ \Omega,$ $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2		$\text{V}$	
			Full range	0 to 3.5				
$V_{OH}$	High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	4.99			$\text{V}$	
			25°C	$I_{OH} = -200\ \mu\text{A}$	4.85	4.93		
				Full range	4.85			
			25°C	$I_{OH} = -1\text{ mA}$	4.25	4.65		
Full range	4.25							
$V_{OL}$	Low-level output voltage	$V_{IC} = 2.5\text{ V},$ $I_{OL} = 50\ \mu\text{A}$	25°C	0.01			$\text{V}$	
			25°C	$I_{OL} = 500\ \mu\text{A}$	0.09	0.15		
				Full range	0.15			
			25°C	$I_{OL} = 5\text{ mA}$	0.9	1.5		
Full range	1.5							
$A_{VD}$	Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V},$ $V_{O} = 1\text{ V to }4\text{ V}$	25°C	$R_L = 10\text{ k}\Omega^\ddagger$	10	35	$\text{V/mV}$	
				Full range	10			
			25°C	$R_L = 1\text{ m}\Omega^\ddagger$	175			
$r_{id}$	Differential input resistance		25°C	10 <sup>12</sup>			$\Omega$	
$r_i$	Common-mode input resistance		25°C	10 <sup>12</sup>			$\Omega$	
$z_o$	Closed-loop output impedance	$f = 1\text{ MHz},$ $A_V = 10$	25°C	140			$\Omega$	
CMRR	Common-mode rejection ratio	$V_{IC} = 0\text{ V to }2.7\text{ V},$ $V_{O} = 2.5\text{ V},$ $R_S = 50\ \Omega$	25°C	70	75		dB	
			Full range	70				
$k_{SVR}$	Supply-voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }16\text{ V},$ $V_{IC} = V_{DD}/2,$ No load	25°C	80	95		dB	
			Full range	80				
$I_{DD}$	Supply current	$V_{O} = 2.5\text{ V},$ No load	25°C	2.2	3		mA	
			Full range			3		

† Full range is -55°C to 125°C for M level part.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2272A-EP TLC2274A-EP**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS131 – JULY 2002

**TLC2272A operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER		TEST CONDITIONS		$T_A$ †	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = 1.25\text{ V to }2.75\text{ V}$ , $R_L = 10\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡		25°C	2.3	3.6		V/ $\mu\text{s}$
				Full range	1.7			
$V_n$	Equivalent input noise voltage	$f = 10\text{ Hz}$		25°C		50		nV/ $\sqrt{\text{Hz}}$
				$f = 1\text{ kHz}$	25°C		9	
$V_{NPP}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		25°C		1		$\mu\text{V}$
				$f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		1.4	
$I_n$	Equivalent input noise current			25°C		0.6		fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O = 0.5\text{ V to }2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ ‡,		$A_V = 1$	25°C	0.0013%		
				$A_V = 10$		0.004%		
				$A_V = 100$		0.03%		
Gain-bandwidth product		$f = 10\text{ kHz}$ , $C_L = 100\text{ pF}$ ‡	$R_L = 10\text{ k}\Omega$ ‡,	25°C		2.18		MHz
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$ , $R_L = 10\text{ k}\Omega$ ‡,	$A_V = 1$ , $C_L = 100\text{ pF}$ ‡	25°C		1		MHz
$t_s$	Settling time	$A_V = -1$ , Step = $0.5\text{ V to }2.5\text{ V}$ , $R_L = 10\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡		$T_o = 0.1\%$	25°C	1.5		$\mu\text{s}$
				$T_o = 0.01\%$		2.6		
$\phi_m$	Phase margin at unity gain	$R_L = 10\text{ k}\Omega$ ‡, $C_L = 100\text{ pF}$ ‡		25°C		50°		
Gain margin				25°C		10		dB

† Full range is  $-55^\circ\text{C to }125^\circ\text{C}$  for M level part.

‡ Referenced to  $2.5\text{ V}$



**TLC2272A electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5$  V (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	$T_A^\dagger$	MIN	TYP	MAX	UNIT
$V_{IO}$	Input offset voltage	$V_{IC} = 0$ V, $V_O = 0$ V, $R_S = 50$ $\Omega$	25°C		300	950	$\mu$ V
			Full range			1500	
$\alpha_{VIO}$	Temperature coefficient of input offset voltage		25°C to 125°C		2		$\mu$ V/°C
			Input offset voltage long-term drift (see Note 4)	25°C	0.002		
$I_{IO}$	Input offset current		25°C		0.5	60	pA
			Full range			800	
$I_{IB}$	Input bias current		25°C		1	60	pA
			Full range			800	
$V_{ICR}$	Common-mode input voltage	$R_S = 50$ $\Omega$ , $ V_{IO}  \leq 5$ mV	25°C	-5 to 4	-5.3 to 4.2		V
			Full range		-5 to 3.5		
$V_{OM+}$	Maximum positive peak output voltage	$I_O = -20$ $\mu$ A	25°C		4.99		V
			25°C		4.85	4.93	
			Full range		4.85		
			25°C		4.25	4.65	
$V_{OM-}$	Maximum negative peak output voltage	$I_O = -1$ mA	25°C		-4.99		V
			25°C		-4.85	-4.91	
			Full range		-4.85		
			25°C		-3.5	-4.1	
$A_{VD}$	Large-signal differential voltage amplification	$V_O = \pm 4$ V	$R_L = 10$ k $\Omega$	25°C	20	50	V/mV
				Full range	20		
			$R_L = 1$ m $\Omega$	25°C		300	
$r_{id}$	Differential input resistance		25°C		$10^{12}$		$\Omega$
$r_i$	Common-mode input resistance		25°C		$10^{12}$		$\Omega$
$z_o$	Closed-loop output impedance	$f = 1$ MHz, $A_V = 10$	25°C		130		$\Omega$
CMRR	Common-mode rejection ratio	$V_{IC} = -5$ V to 2.7 V, $V_O = 0$ V, $R_S = 50$ $\Omega$	25°C	75	80		dB
			Full range	75			
$k_{SVR}$	Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = \pm 2.2$ V to $\pm 8$ V, $V_{IC} = 0$ V, No load	25°C	80	95		dB
			Full range	80			
$I_{DD}$	Supply current	$V_O = 2.5$ V, No load	25°C	2.4	3		mA
			Full range			3	

$^\dagger$  Full range is -55°C to 125°C for M level part.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ$ C extrapolated to  $T_A = 25^\circ$ C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2272A-EP TLC2274A-EP**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS131 – JULY 2002

**TLC2272A operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER		TEST CONDITIONS		$T_A$ †	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = \pm 1\text{ V}$ , $C_L = 100\text{ pF}$	$R_L = 10\text{ k}\Omega$ ,	25°C	2.3	3.6		V/ $\mu$ s
				Full range	1.7			
$V_n$	Equivalent input noise voltage			25°C		50		nV/ $\sqrt{\text{Hz}}$
						9		
$V_{NPP}$	Peak-to-peak equivalent input noise voltage			25°C		1		$\mu$ V
						1.4		
$I_n$	Equivalent input noise current			25°C		0.6		fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O = \pm 2.3\text{ V}$ $R_L = 10\text{ k}\Omega$ , $f = 20\text{ kHz}$		25°C		$A_V = 1$	0.0011%	
						$A_V = 10$	0.004%	
						$A_V = 100$	0.03%	
	Gain-bandwidth product	$f = 10\text{ kHz}$ , $C_L = 100\text{ pF}$	$R_L = 10\text{ k}\Omega$ ,	25°C		2.25		MHz
$B_{OM}$	Maximum output-swing bandwidth	$V_{O(PP)} = 4.6\text{ V}$ , $R_L = 10\text{ k}\Omega$ ,	$A_V = 1$ , $C_L = 100\text{ pF}$	25°C		0.54		MHz
$t_s$	Settling time	$A_V = -1$ , Step = $-2.3\text{ V}$ to $2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$		25°C	$T_o = 0.1\%$	1.5		$\mu$ s
					$T_o = 0.01\%$	3.2		
$\phi_m$	Phase margin at unity gain			25°C		52°		
	Gain margin	$R_L = 10\text{ k}\Omega$ ,	$C_L = 100\text{ pF}$	25°C		10		dB

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.





**TLC2274A electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	$T_A^\dagger$	MIN	TYP	MAX	UNIT	
$V_{IO}$	Input offset voltage	$V_{DD} = \pm 2.5\text{ V}, V_{IC} = 0\text{ V}, V_O = 0\text{ V}, R_S = 50\ \Omega$	25°C		300	950	$\mu\text{V}$	
			Full range			1500		
$\alpha_{VIO}$	Temperature coefficient of input offset voltage		25°C to 125°C		2		$\mu\text{V}/^\circ\text{C}$	
			Input offset voltage long-term drift (see Note 4)	25°C	0.002			$\mu\text{V}/\text{mo}$
$I_{IO}$	Input offset current		25°C		0.5	60	$\text{pA}$	
			Full range			800		
$I_{IB}$	Input bias current		25°C		1	60	$\text{pA}$	
			Full range			800		
$V_{ICR}$	Common-mode input voltage		$R_S = 50\ \Omega,  V_{IO}  \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2		$\text{V}$
				Full range	0 to 3.5			
$V_{OH}$	High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C		4.99		$\text{V}$	
			25°C		4.85	4.93		
			Full range		4.85			
			25°C		4.25	4.65		
$V_{OL}$	Low-level output voltage	$I_{OH} = -1\text{ mA}$	25°C		0.01		$\text{V}$	
			25°C		0.09	0.15		
			Full range			0.15		
			25°C		0.9	1.5		
$A_{VD}$	Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}, V_O = 1\text{ V to }4\text{ V}$	$R_L = 10\text{ k}\Omega^\ddagger$	25°C	10	35	$\text{V}/\text{mV}$	
				Full range	10			
			$R_L = 1\text{ M}\Omega^\ddagger$	25°C		175		
				Full range				
$r_{id}$	Differential input resistance		25°C		$10^{12}$	$\Omega$		
$r_i$	Common-mode input resistance		25°C		$10^{12}$	$\Omega$		
$z_o$	Closed-loop output impedance	$f = 1\text{ MHz}, A_V = 10$	25°C		140	$\Omega$		
CMRR	Common-mode rejection ratio	$V_{IC} = 0\text{ V to }2.7\text{ V}, V_O = 2.5\text{ V}, R_S = 50\ \Omega$	25°C	70	75	$\text{dB}$		
			Full range	70				
$k_{SVR}$	Supply-voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }16\text{ V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C	80	95	$\text{dB}$		
			Full range	80				
$I_{DD}$	Supply current	$V_O = 2.5\text{ V}, \text{ No load}$	25°C	4.4	6	$\text{mA}$		
			Full range		6			

$^\dagger$  Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

$^\ddagger$  Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2272A-EP TLC2274A-EP**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS131 – JULY 2002

**TLC2274A operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER		TEST CONDITIONS		$T_A$ †	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = 0.5\text{ V to }2.5\text{ V}, C_L = 100\text{ pF}‡$ $R_L = 10\text{ k}\Omega‡$ ,		25°C	2.3	3.6		V/ $\mu$ s
				Full range	1.7			
$V_n$	Equivalent input noise voltage			25°C	50			nV/ $\sqrt{\text{Hz}}$
				25°C	9			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage			25°C	1			$\mu$ V
				25°C	1.4			
$I_n$	Equivalent input noise current			25°C	0.6			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O = 0.5\text{ V to }2.5\text{ V}, f = 20\text{ kHz}, R_L = 10\text{ k}\Omega‡$		25°C	$A_V = 1$		0.0013%	
					$A_V = 10$		0.004%	
					$A_V = 100$		0.03%	
Gain-bandwidth product		$f = 10\text{ kHz}, C_L = 100\text{ pF}‡$	$R_L = 10\text{ k}\Omega‡$ ,	25°C	2.18			MHz
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}, R_L = 10\text{ k}\Omega‡$ ,	$A_V = 1, C_L = 100\text{ pF}‡$	25°C	1			MHz
$t_s$	Settling time	$A_V = -1, \text{ Step} = 0.5\text{ V to }2.5\text{ V}, R_L = 10\text{ k}\Omega‡, C_L = 100\text{ pF}‡$		25°C	$T_o = 0.1\%$		1.5	$\mu$ s
					$T_o = 0.01\%$		2.6	
$\phi_m$	Phase margin at unity gain	$R_L = 10\text{ k}\Omega‡, C_L = 100\text{ pF}‡$		25°C	50°			
	Gain margin			25°C	10			dB

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

‡ Referenced to 2.5 V



**TLC2274A electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	$T_A^\dagger$	MIN	TYP	MAX	UNIT	
$V_{IO}$	Input offset voltage	$V_{IC} = 0\text{ V}, V_O = 0\text{ V}, R_S = 50\ \Omega$	25°C	300	950		$\mu\text{V}$	
			Full range		1500			
$\alpha_{VIO}$	Temperature coefficient of input offset voltage		25°C to 125°C	2			$\mu\text{V}/^\circ\text{C}$	
	Input offset voltage long-term drift (see Note 4)		25°C	0.002			$\mu\text{V}/\text{mo}$	
$I_{IO}$	Input offset current		25°C	0.5	60		$\text{pA}$	
			Full range		800			
$I_{IB}$	Input bias current		25°C	1	60		$\text{pA}$	
			Full range		800			
$V_{ICR}$	Common-mode input voltage	$R_S = 50\ \Omega,  V_{IO}  \leq 5\text{ mV}$	25°C	-5 to 4	-5.3 to 4.2		$\text{V}$	
			Full range		-5 to 3.5			
$V_{OM+}$	Maximum positive peak output voltage	$I_O = -20\ \mu\text{A}$	25°C	4.99			$\text{V}$	
			25°C	4.85	4.93			
			Full range	4.85				
			25°C	4.25	4.65			
$V_{OM-}$	Maximum negative peak output voltage	$I_O = -1\text{ mA}$	25°C	-4.99			$\text{V}$	
			25°C	-4.85	-4.91			
			Full range	-4.85				
			25°C	-3.5	-4.1			
$A_{VD}$	Large-signal differential voltage amplification	$V_O = \pm 4\text{ V}$	$R_L = 10\text{ k}\Omega$	25°C	20	50	$\text{V/mV}$	
				Full range	20			
			$R_L = 1\text{ M}\Omega$	25°C	300			
				Full range				
$r_{id}$	Differential input resistance		25°C	$10^{12}$		$\Omega$		
$r_i$	Common-mode input resistance		25°C	$10^{12}$		$\Omega$		
$z_o$	Closed-loop output impedance	$f = 1\text{ MHz}, A_V = 10$	25°C	130		$\Omega$		
CMRR	Common-mode rejection ratio	$V_{IC} = -5\text{ V to } 2.7\text{ V}, V_O = 0\text{ V}, R_S = 50\ \Omega$	25°C	75	80		dB	
			Full range	75				
$k_{SVR}$	Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.2\text{ V to } \pm 8\text{ V}, V_{IC} = 0\text{ V}, \text{ No load}$	25°C	80	95		dB	
			Full range	80				
$I_{DD}$	Supply current	$V_O = 0\text{ V}, \text{ No load}$	25°C	4.8	6		$\text{mA}$	
			Full range		6			

$^\dagger$  Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

**TLC2272A-EP TLC2274A-EP**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

SGLS131 – JULY 2002

**TLC2274A operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER		TEST CONDITIONS		$T_A$ †	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	$V_O = \pm 2.3\text{ V}$ , $C_L = 100\text{ pF}$	$R_L = 10\text{ k}\Omega$	25°C	2.3	3.6		V/ $\mu\text{s}$
				Full range	1.7			
$V_n$	Equivalent input noise voltage	f = 10 Hz		25°C		50		nV/ $\sqrt{\text{Hz}}$
		f = 1 kHz		25°C		9		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C		1		$\mu\text{V}$
		f = 0.1 Hz to 10 Hz		25°C		1.4		
$I_n$	Equivalent input noise current			25°C		0.6		fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O = \pm 2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , f = 20 kHz		$A_V = 1$	25°C	0.0011%		
				$A_V = 10$		0.004%		
				$A_V = 100$		0.03%		
Gain-bandwidth product		f = 10 kHz, $C_L = 100\text{ pF}$	$R_L = 10\text{ k}\Omega$	25°C		2.25		MHz
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 4.6\text{ V}$ , $R_L = 10\text{ k}\Omega$	$A_V = 1$ , $C_L = 100\text{ pF}$	25°C		0.54		MHz
$t_s$	Settling time	$A_V = -1$ , Step = $-2.3\text{ V}$ to $2.3\text{ V}$ , $R_L = 10\text{ k}\Omega$ , $C_L = 100\text{ pF}$		To 0.1%	25°C	1.5		$\mu\text{s}$
				To 0.01%		3.2		
$\phi_m$	Phase margin at unit gain			25°C		52°		
	Gain margin	$R_L = 10\text{ k}\Omega$	$C_L = 100\text{ pF}$	25°C		10		dB

† Full range is  $-55^\circ\text{C}$  to  $125^\circ\text{C}$  for M level part.



## TYPICAL CHARACTERISTICS

**Table of Graphs**

		<b>FIGURE</b>	
$V_{IO}$	Input offset voltage	Distribution vs Common-mode voltage	1 – 4 5, 6
$\alpha_{VIO}$	Input offset voltage temperature coefficient	Distribution	7 – 10
$I_{IB}/I_{IO}$	Input bias and input offset current	vs Free-air temperature	11
$V_I$	Input voltage	vs Supply voltage vs Free-air temperature	12 13
$V_{OH}$	High-level output voltage	vs High-level output current	14
$V_{OL}$	Low-level output voltage	vs Low-level output current	15, 16
$V_{OM+}$	Maximum positive peak output voltage	vs Output current	17
$V_{OM-}$	Maximum negative peak output voltage	vs Output current	18
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	19
$I_{OS}$	Short-circuit output current	vs Supply voltage vs Free-air temperature	20 21
$V_O$	Output voltage	vs Differential input voltage	22, 23
$A_{VD}$	Large-signal differential voltage amplification	vs Load resistance	24
	Large-signal differential voltage amplification and phase margin	vs Frequency	25, 26
	Large-signal differential voltage amplification	vs Free-air temperature	27, 28
$z_o$	Output impedance	vs Frequency	29, 30
$CMRR$	Common-mode rejection ratio	vs Frequency	31
		vs Free-air temperature	32
$k_{SVR}$	Supply-voltage rejection ratio	vs Frequency	33, 34
		vs Free-air temperature	35
$I_{DD}$	Supply current	vs Supply voltage	36, 37
		vs Free-air temperature	38, 39
$SR$	Slew rate	vs Load capacitance	40
		vs Free-air temperature	41
$V_O$	Inverting large-signal pulse response		42, 43
	Voltage-follower large-signal pulse response		44, 45
	Inverting small-signal pulse response		46, 47
	Voltage-follower small-signal pulse response		48, 49
$V_n$	Equivalent input noise voltage	vs Frequency	50, 51
	Noise voltage over a 10-second period		52
	Integrated noise voltage	vs Frequency	53
$THD + N$	Total harmonic distortion plus noise	vs Frequency	54
	Gain-bandwidth product	vs Supply voltage	55
		vs Free-air temperature	56
$\phi_m$	Phase margin	vs Load capacitance	57
	Gain margin	vs Load capacitance	58

NOTE: For all graphs where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLC2272  
 INPUT OFFSET VOLTAGE

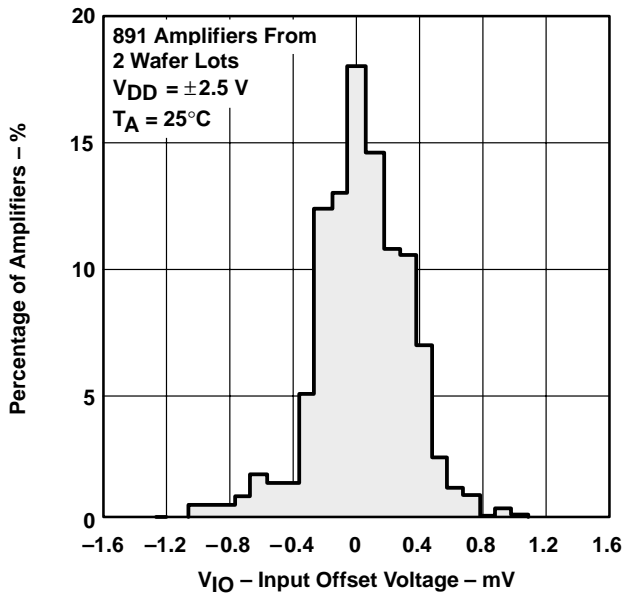


Figure 1

DISTRIBUTION OF TLC2272  
 INPUT OFFSET VOLTAGE

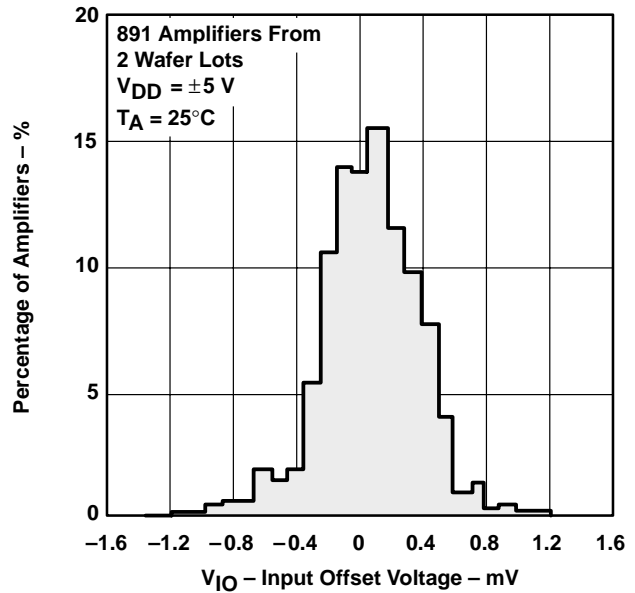


Figure 2

DISTRIBUTION OF TLC2274  
 INPUT OFFSET VOLTAGE

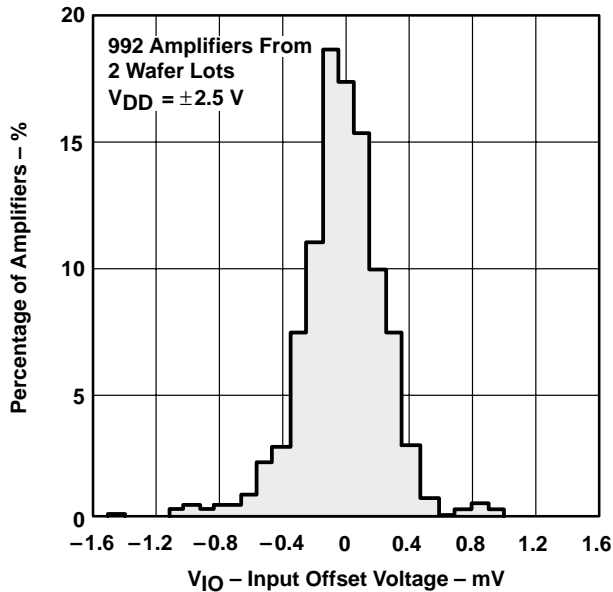


Figure 3

DISTRIBUTION OF TLC2274  
 INPUT OFFSET VOLTAGE

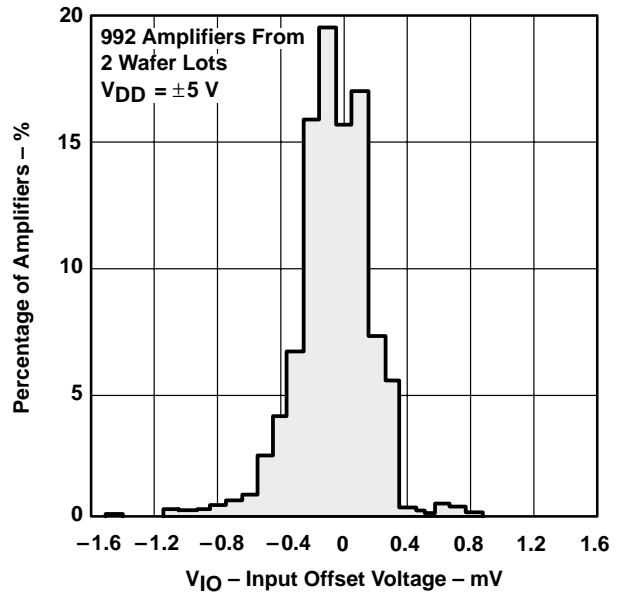


Figure 4

TYPICAL CHARACTERISTICS

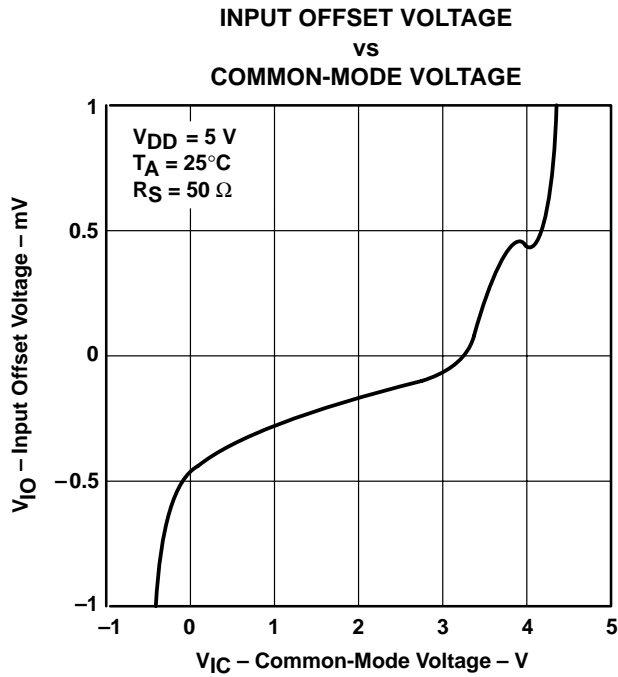


Figure 5

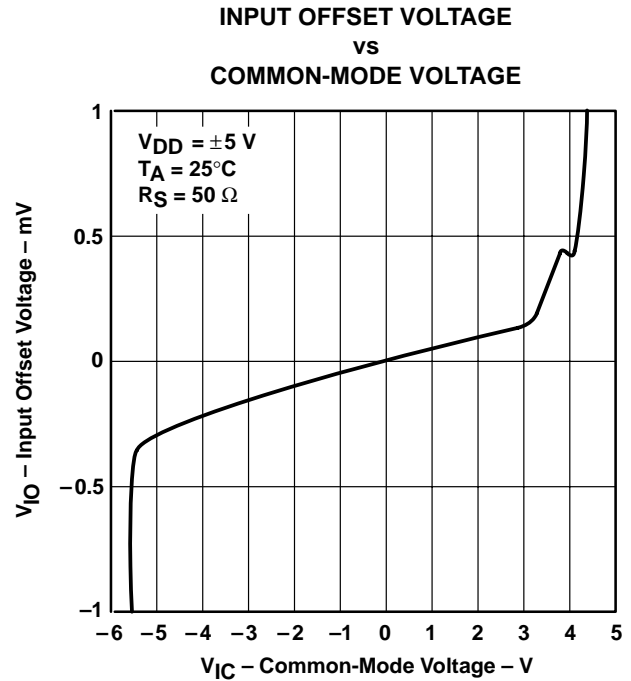


Figure 6

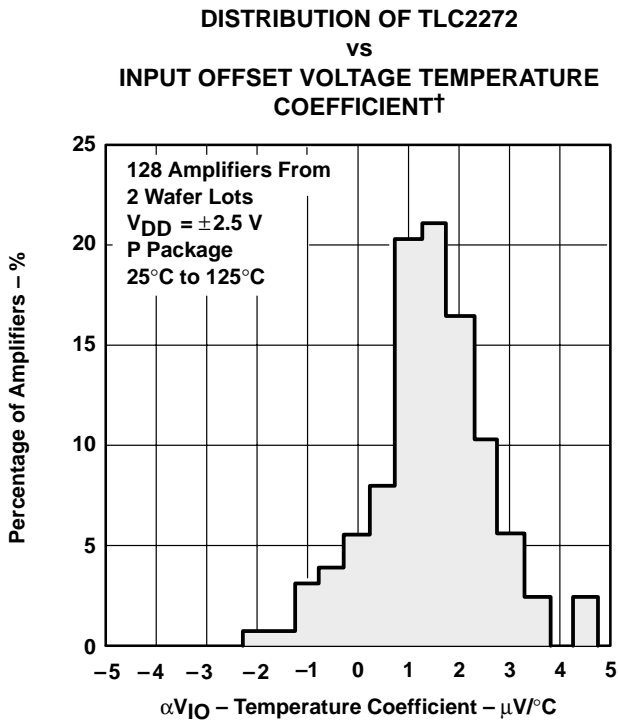


Figure 7

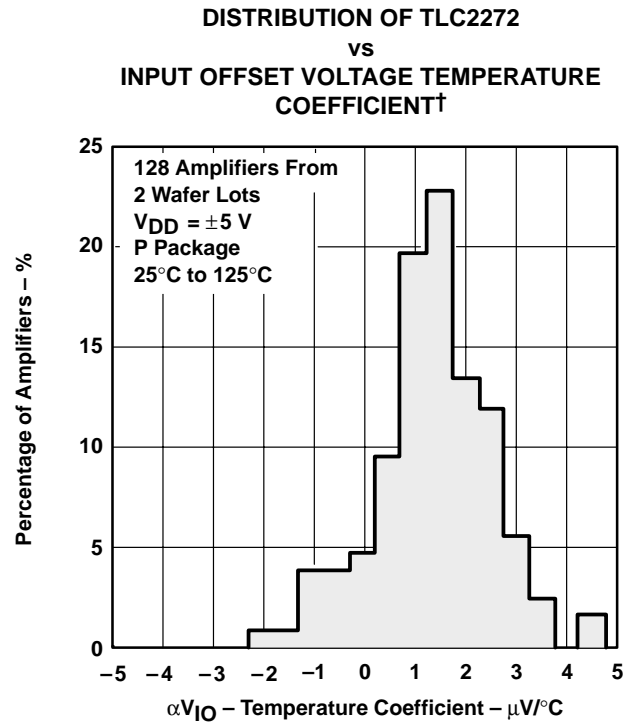


Figure 8

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

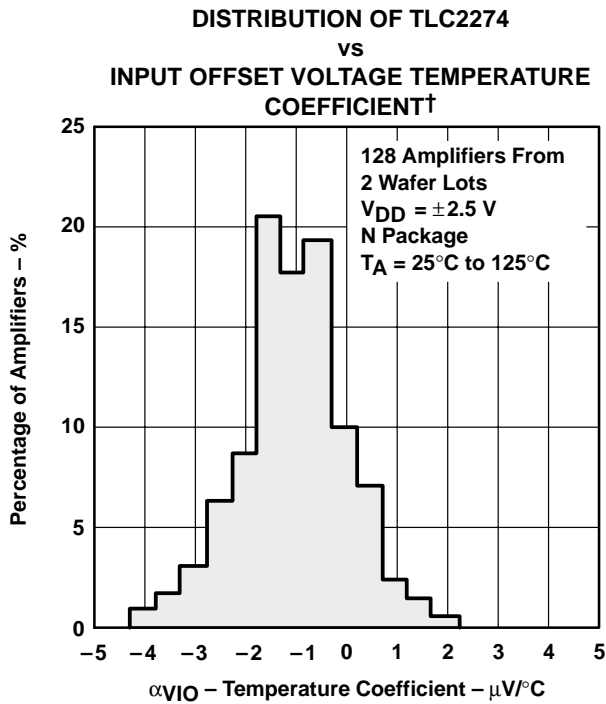


Figure 9

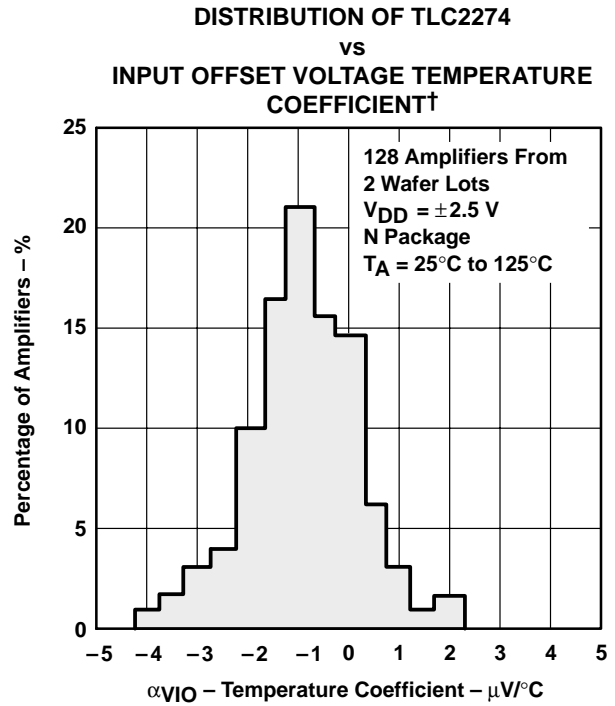


Figure 10

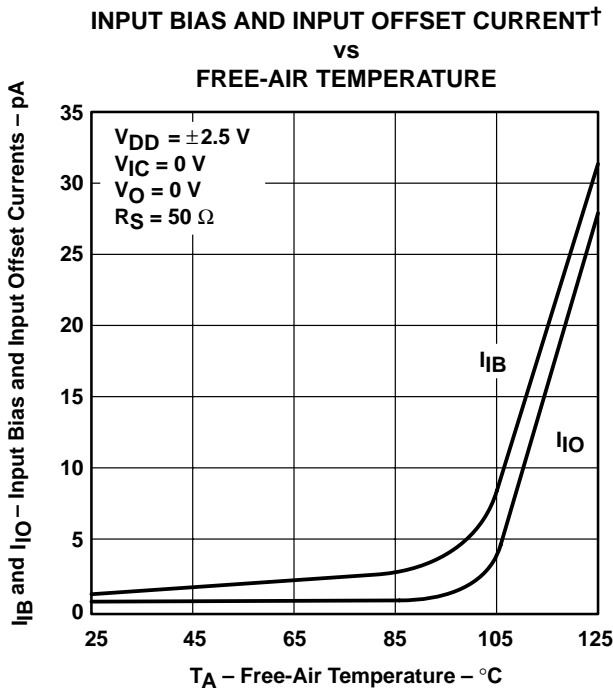


Figure 11

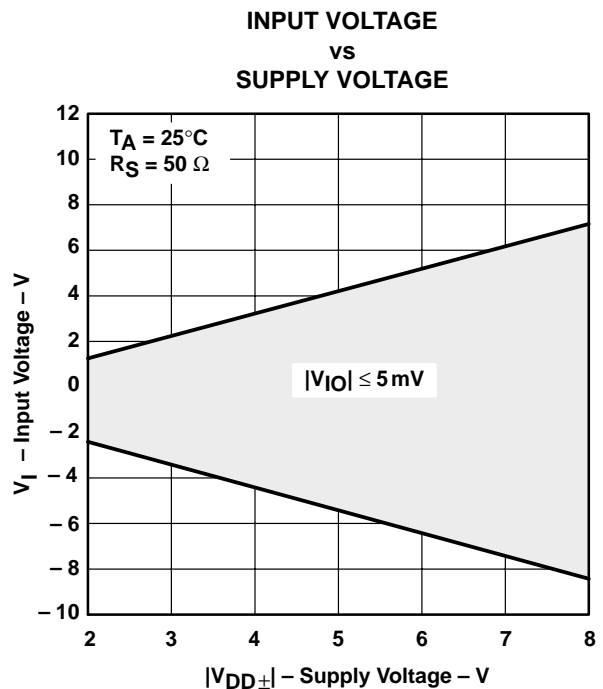


Figure 12

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

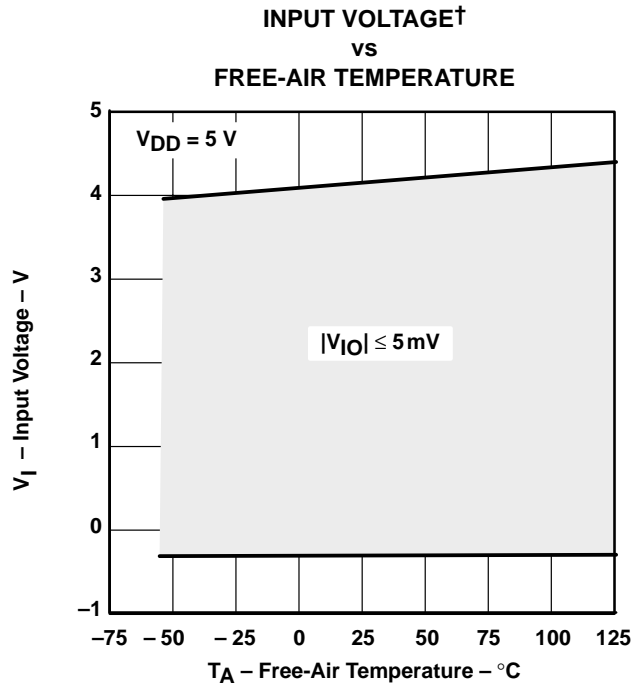


Figure 13

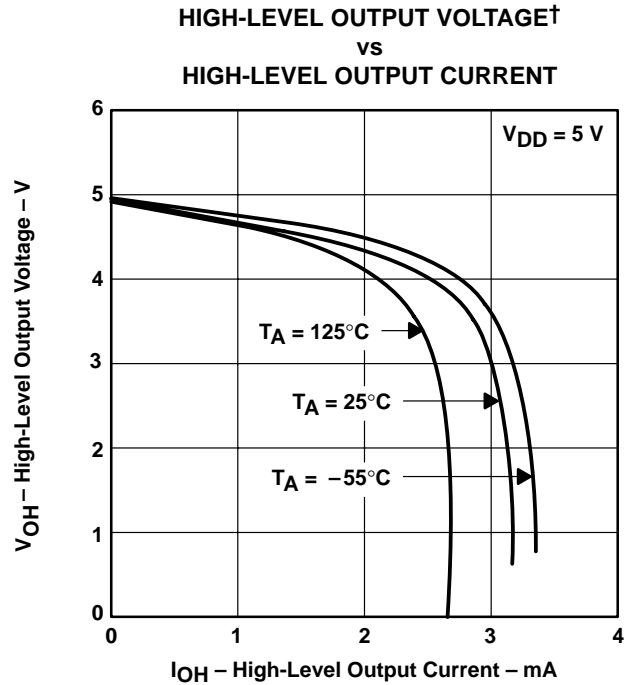


Figure 14

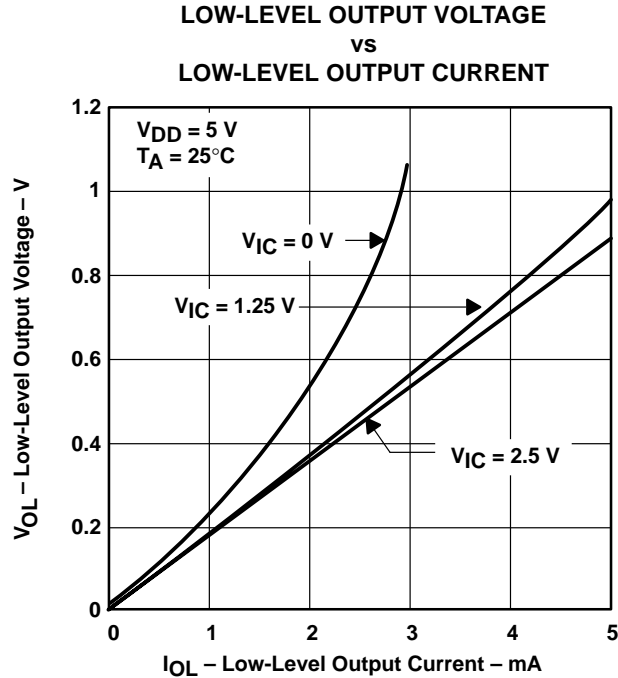


Figure 15

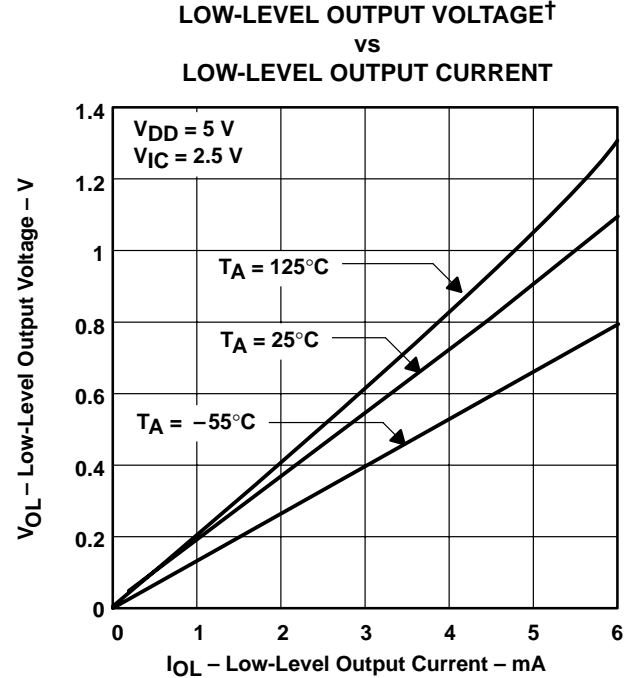


Figure 16

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE†  
 vs  
 OUTPUT CURRENT

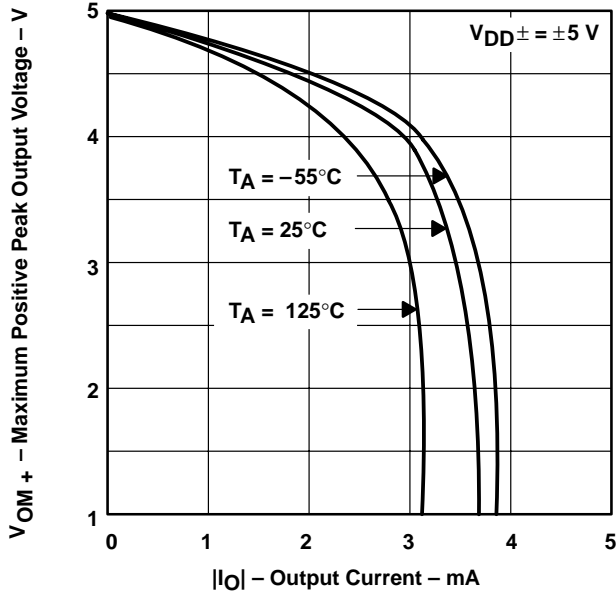


Figure 17

MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE†  
 vs  
 OUTPUT CURRENT

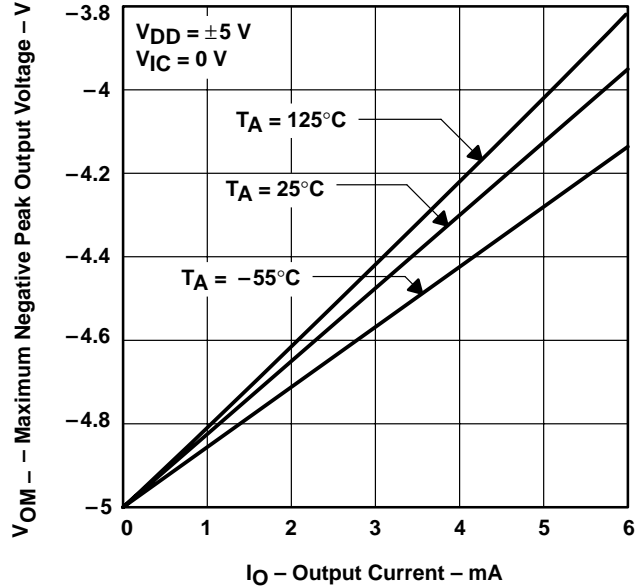


Figure 18

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE  
 vs  
 FREQUENCY

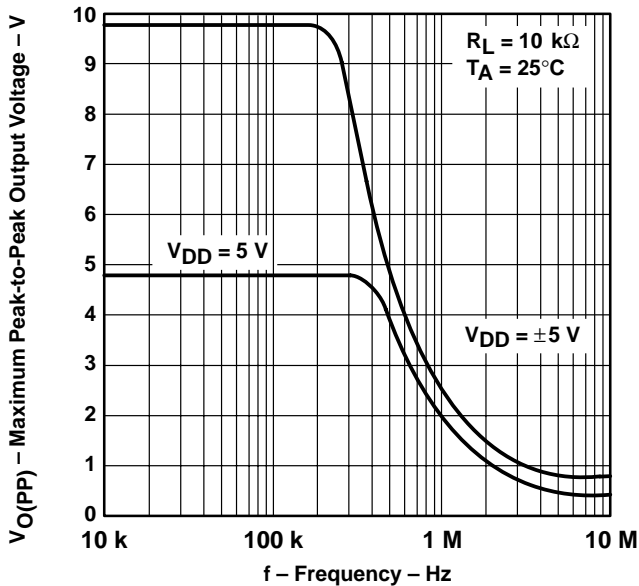


Figure 19

SHORT-CIRCUIT OUTPUT CURRENT  
 vs  
 SUPPLY VOLTAGE

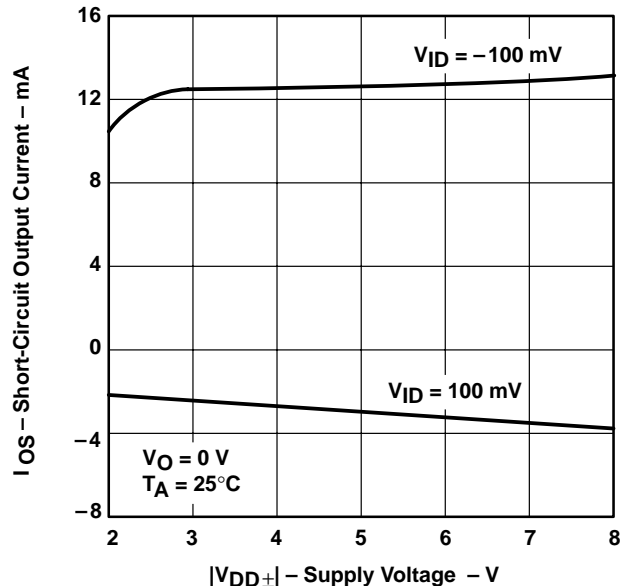


Figure 20

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

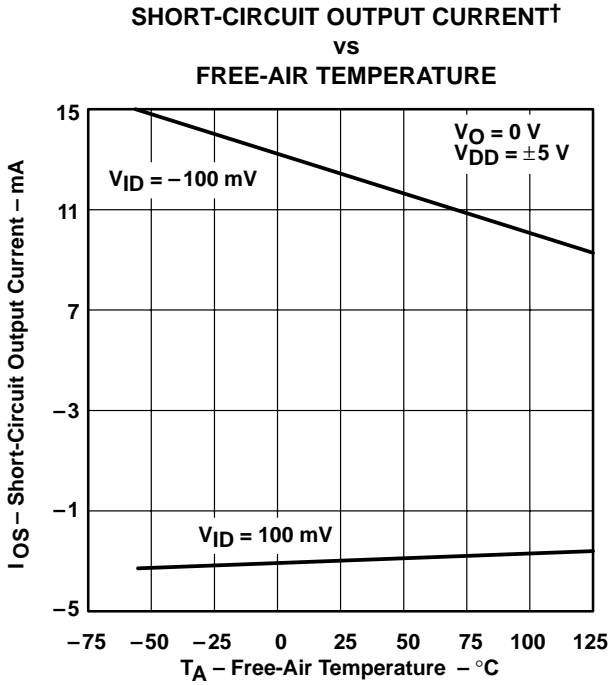


Figure 21

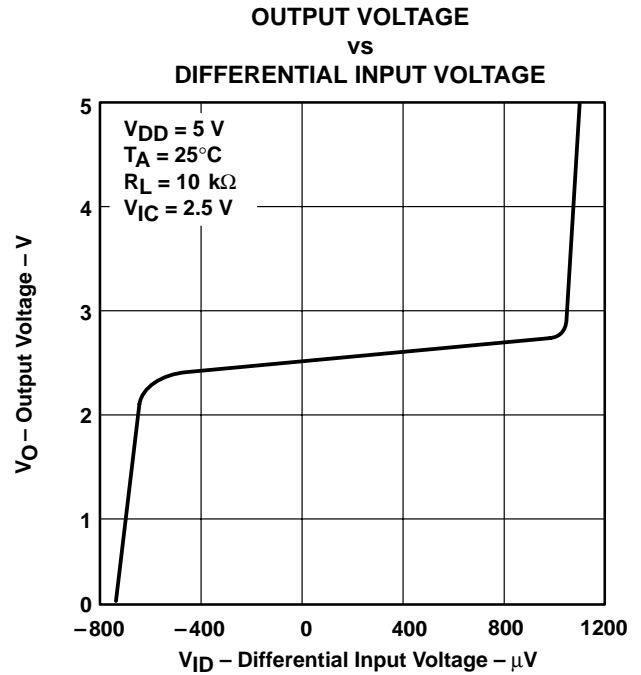


Figure 22

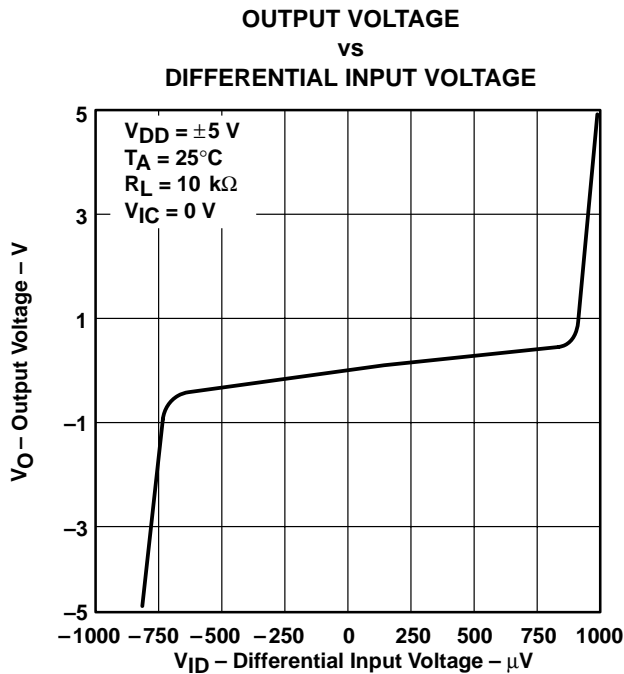


Figure 23

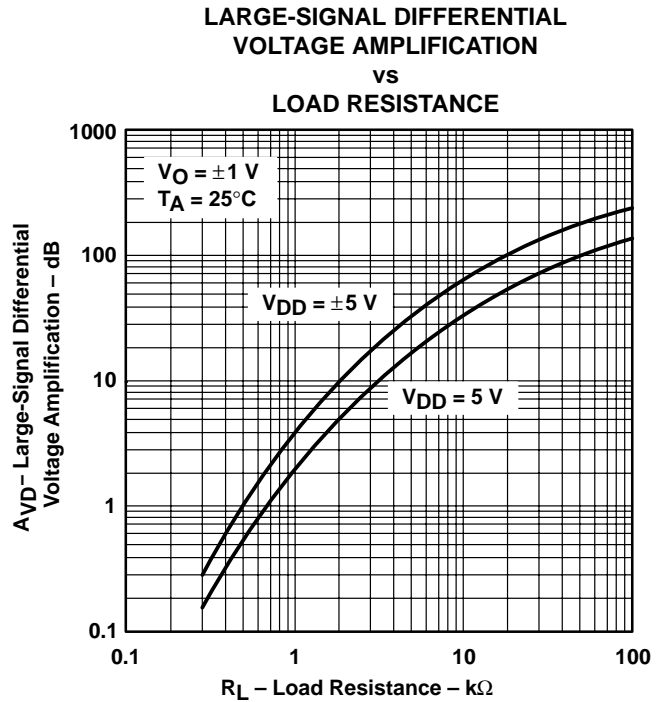


Figure 24

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE  
 AMPLIFICATION AND PHASE MARGIN

vs  
 FREQUENCY

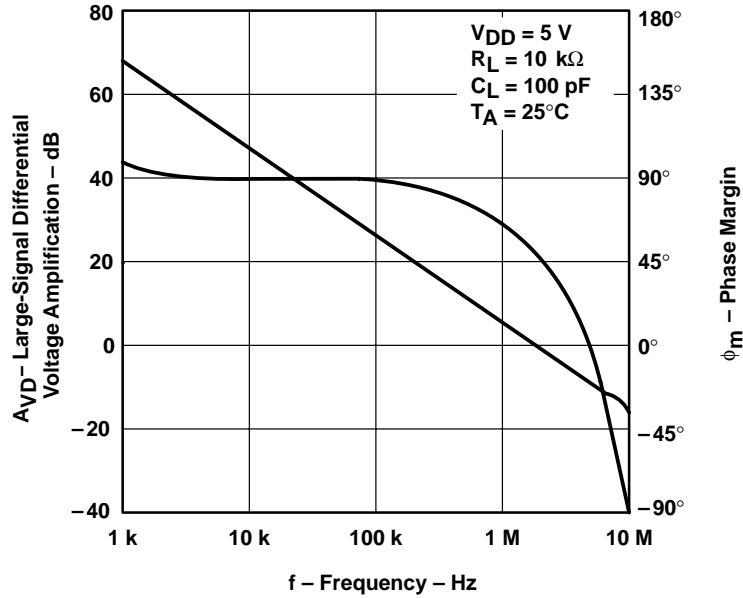


Figure 25

LARGE-SIGNAL DIFFERENTIAL VOLTAGE  
 AMPLIFICATION AND PHASE MARGIN

vs  
 FREQUENCY

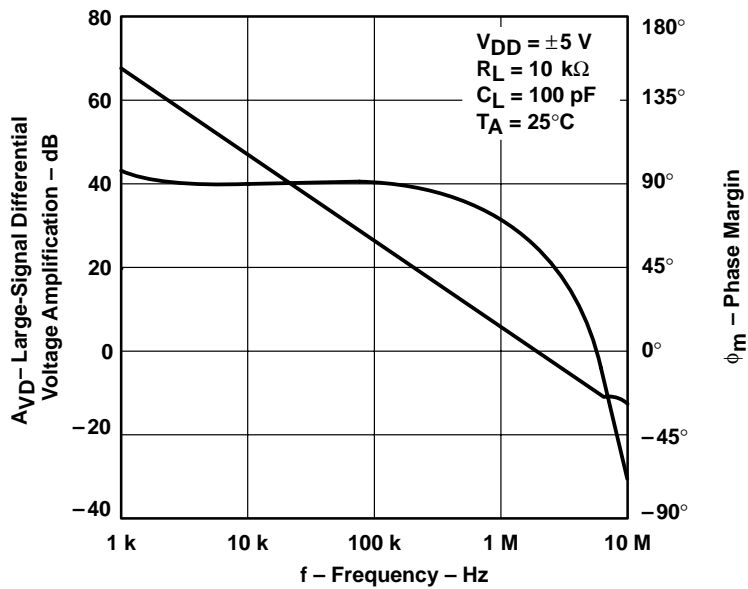
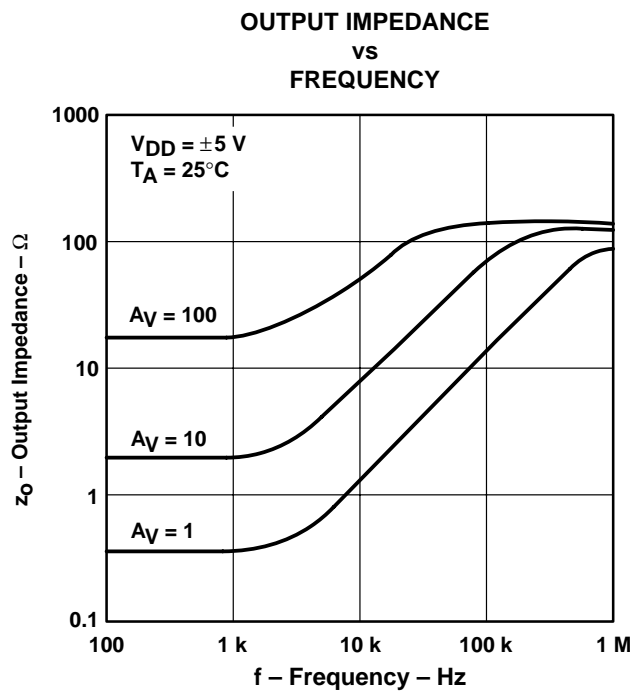
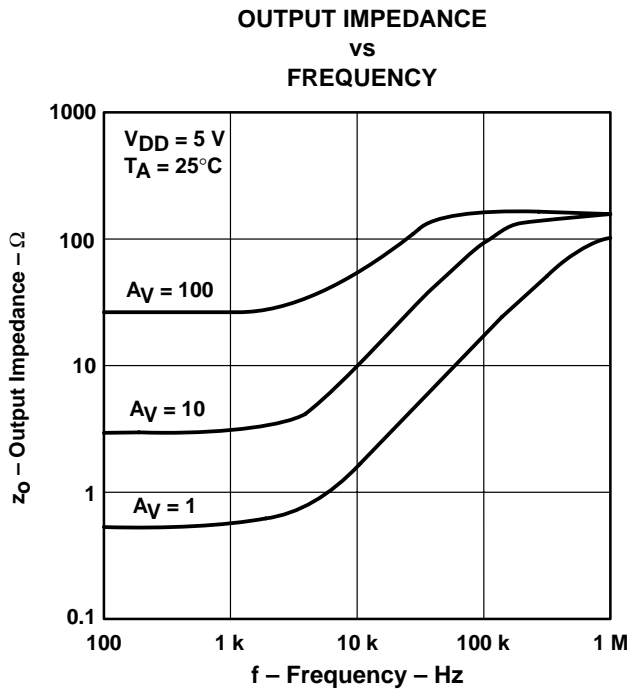
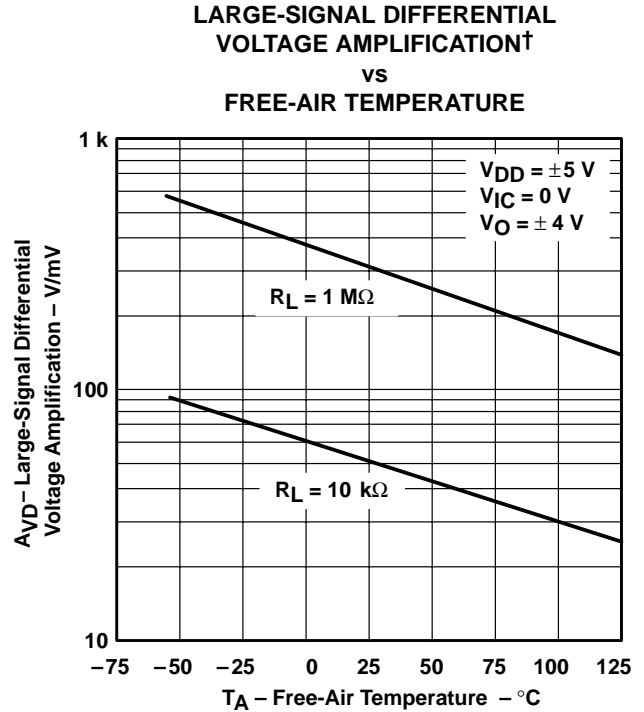
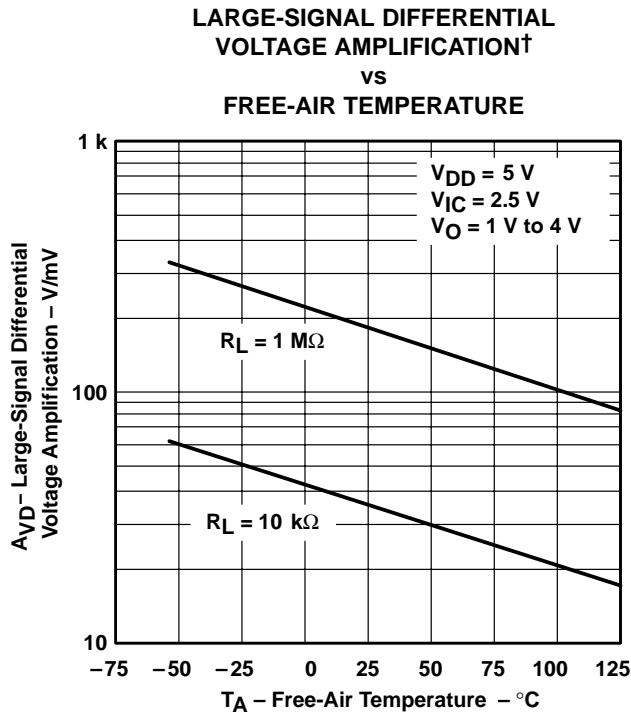


Figure 26

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

COMMON-MODE REJECTION RATIO  
 vs  
 FREQUENCY

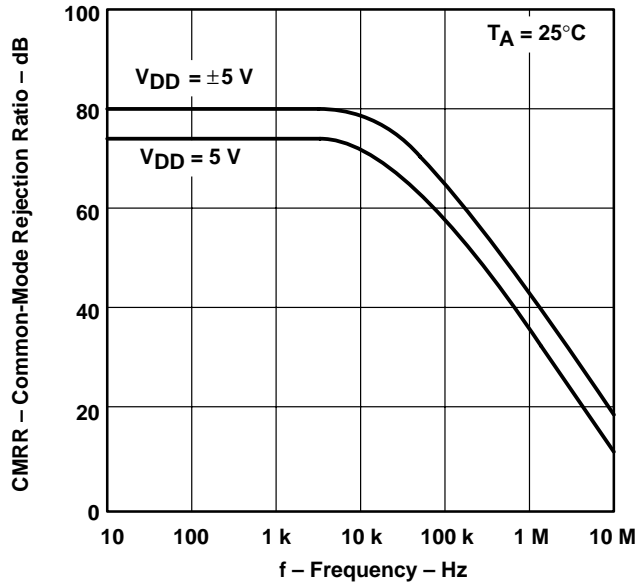


Figure 31

COMMON-MODE REJECTION RATIO  
 vs  
 FREE-AIR TEMPERATURE

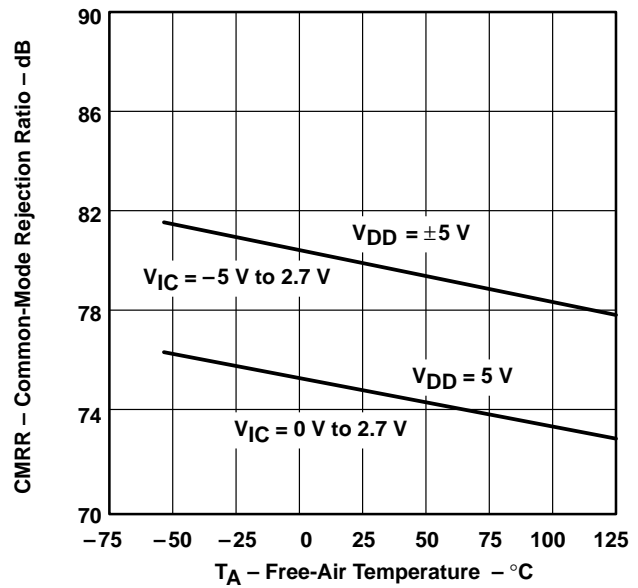


Figure 32

SUPPLY-VOLTAGE REJECTION RATIO  
 vs  
 FREQUENCY

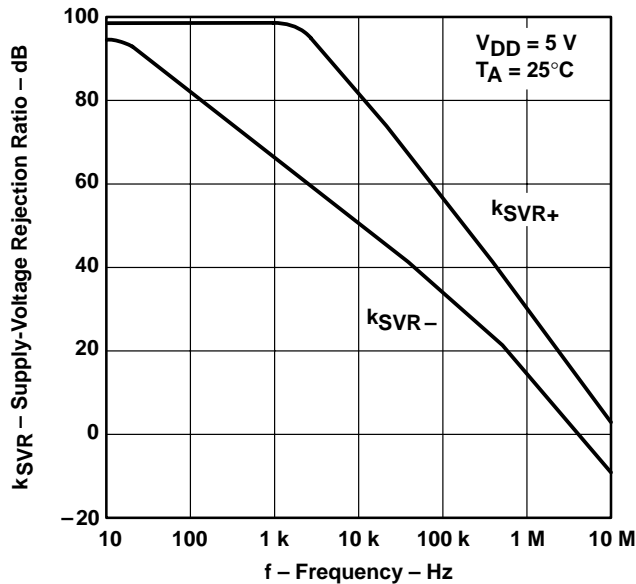


Figure 33

SUPPLY-VOLTAGE REJECTION RATIO  
 vs  
 FREQUENCY

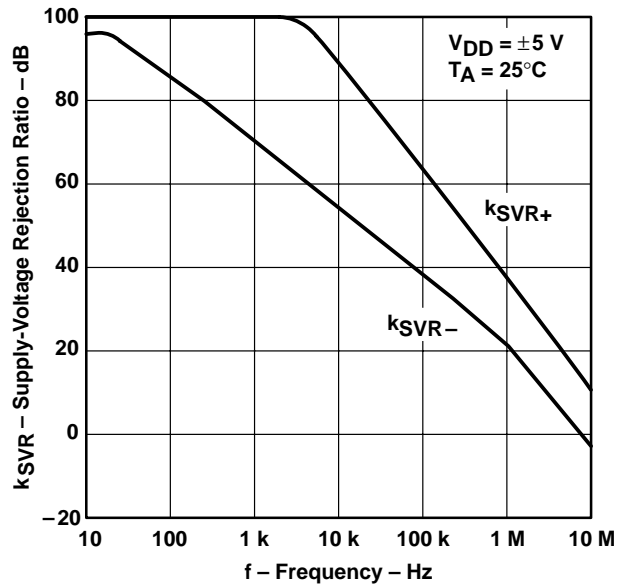
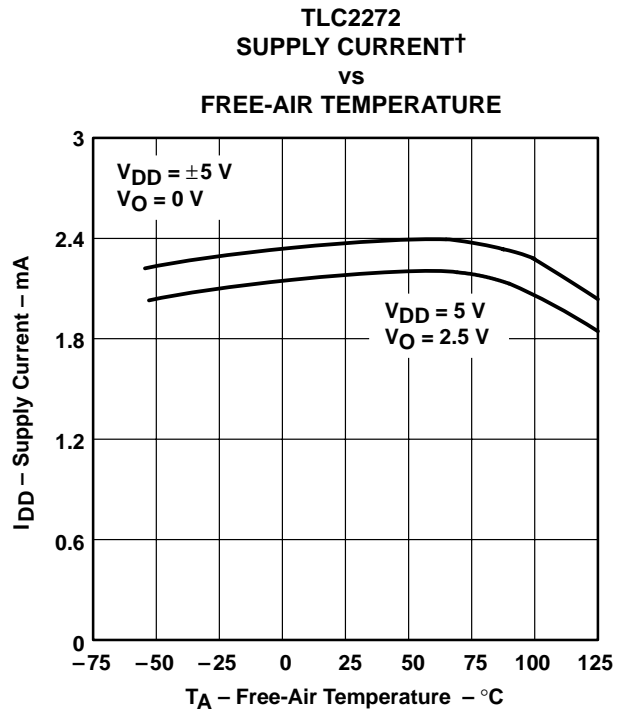
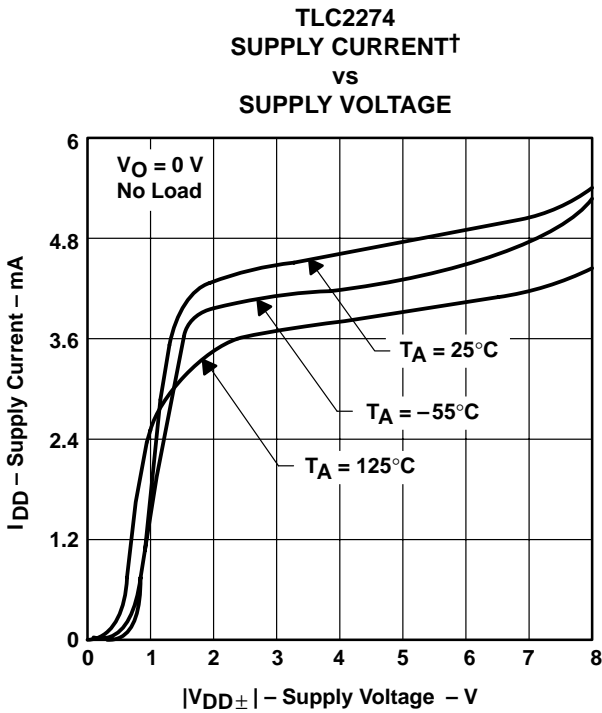
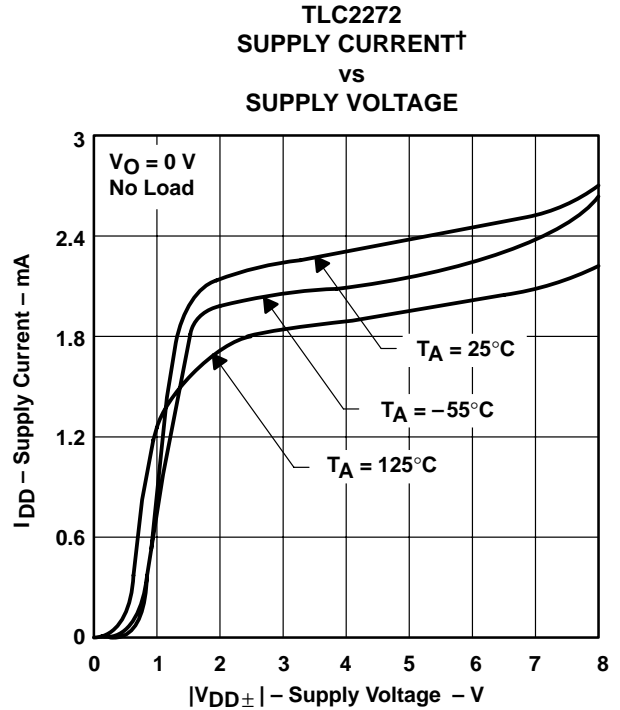
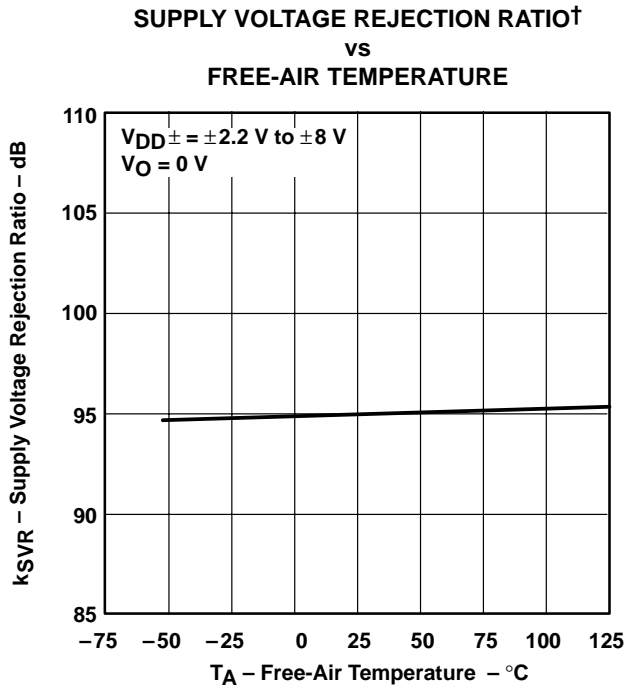


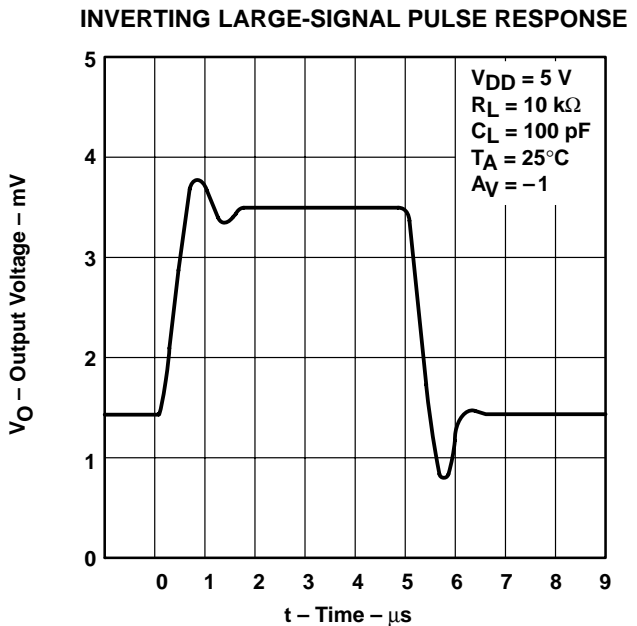
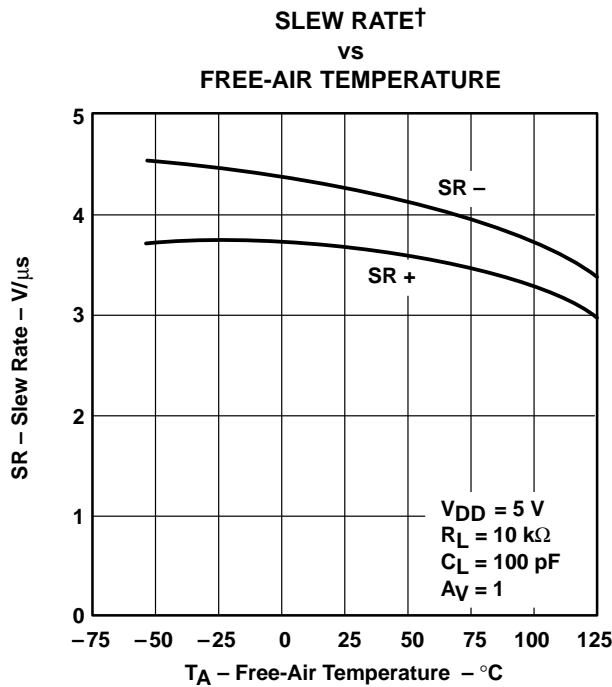
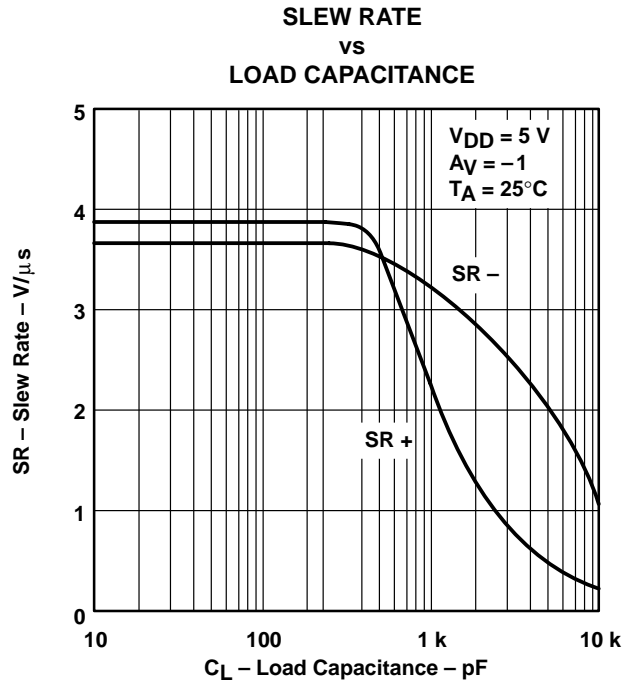
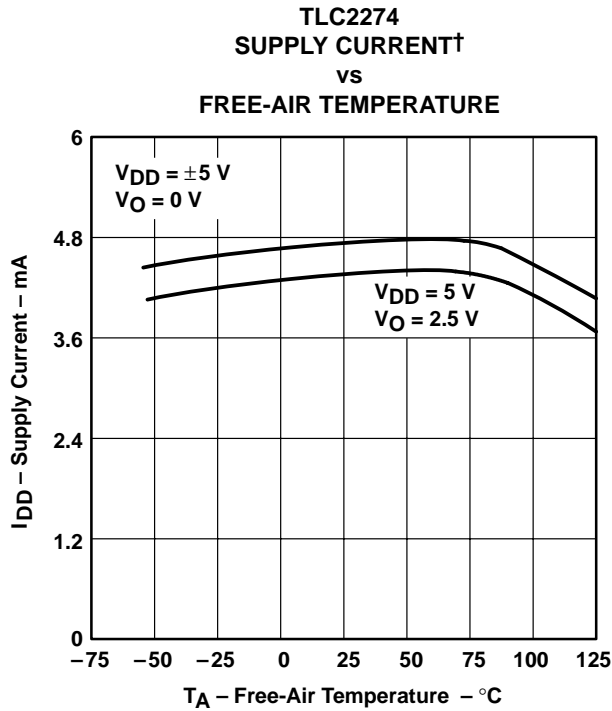
Figure 34

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

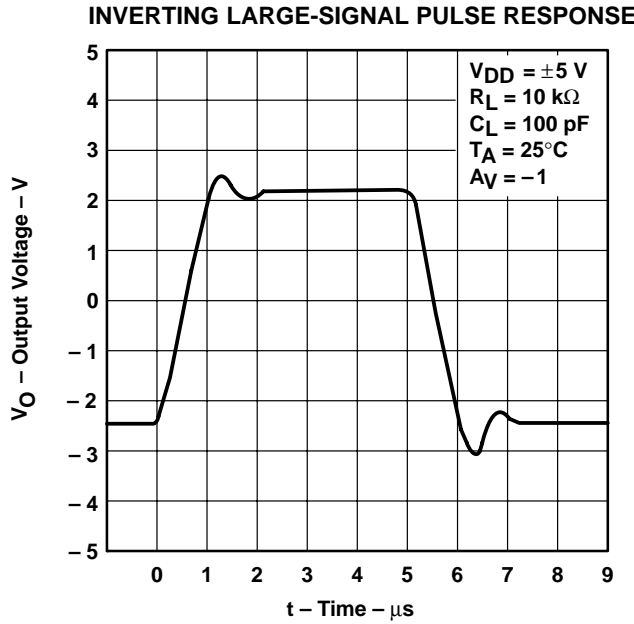


Figure 43

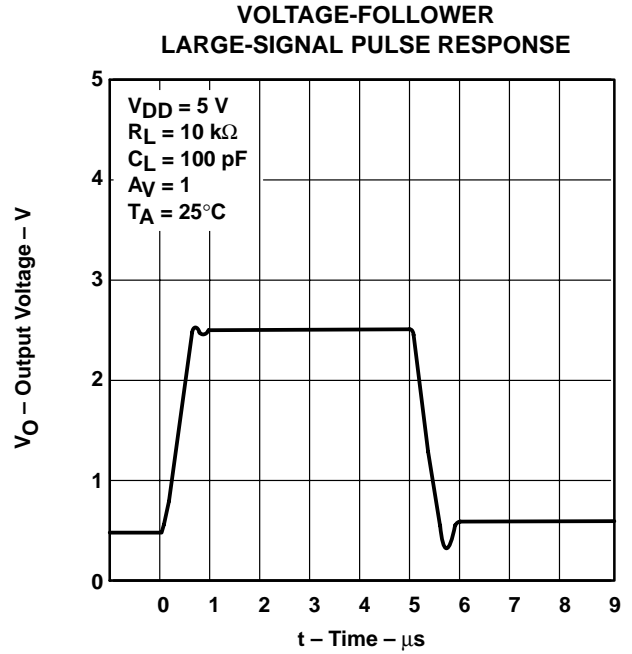


Figure 44

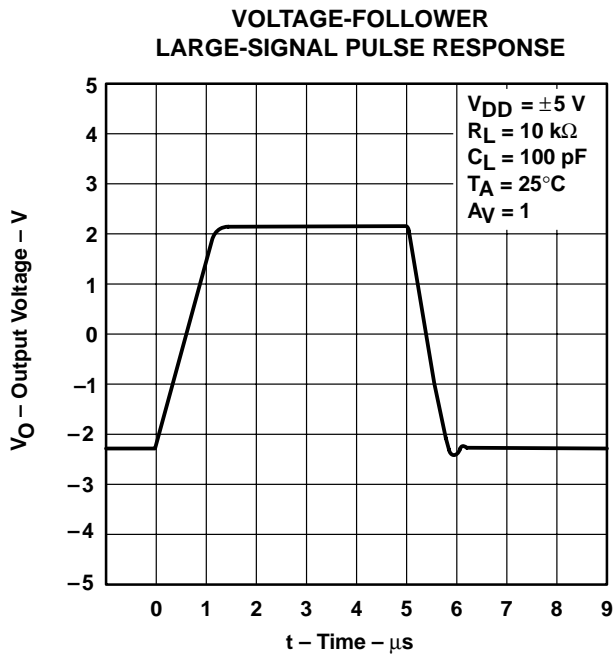


Figure 45

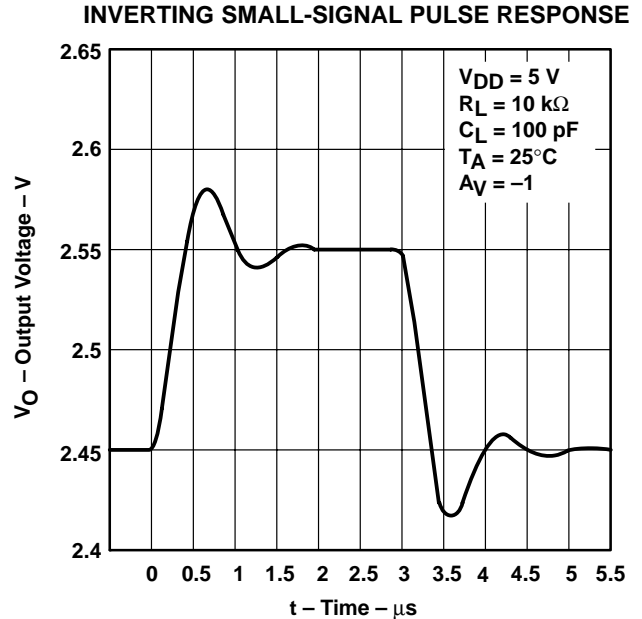


Figure 46

TYPICAL CHARACTERISTICS

INVERTING SMALL-SIGNAL PULSE RESPONSE

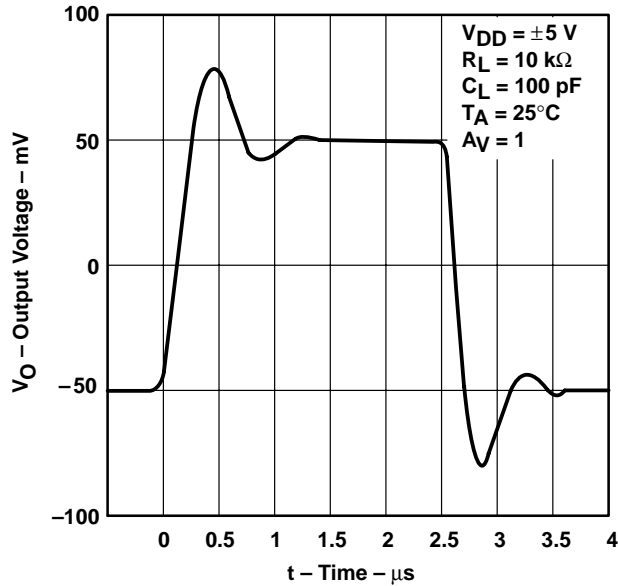


Figure 47

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

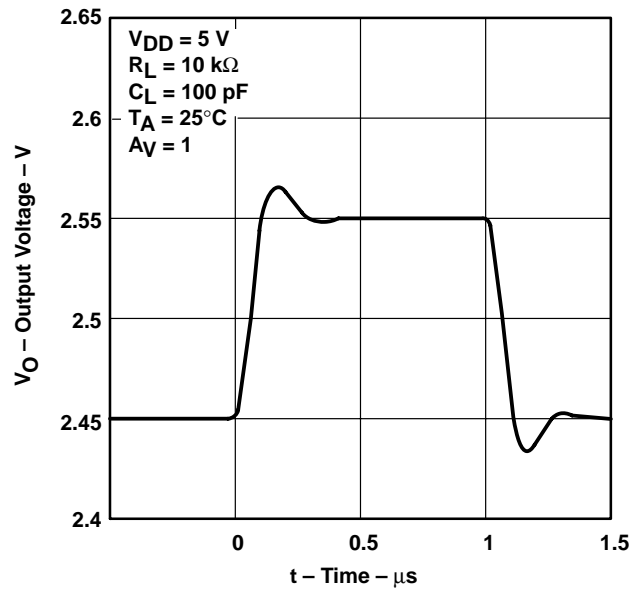


Figure 48

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

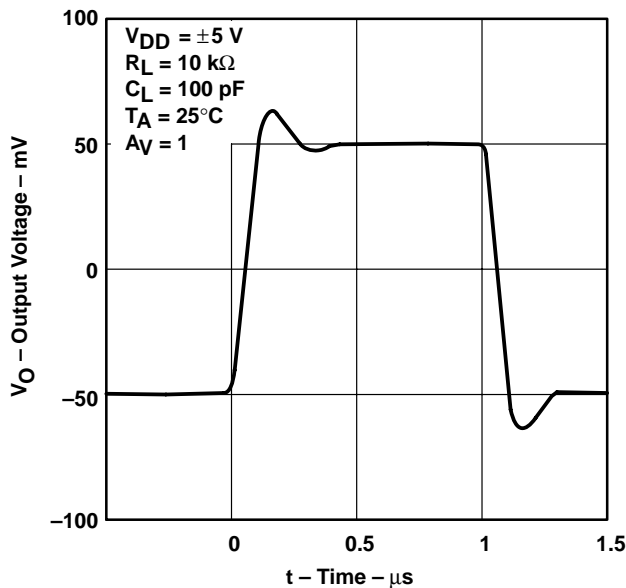


Figure 49

EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY

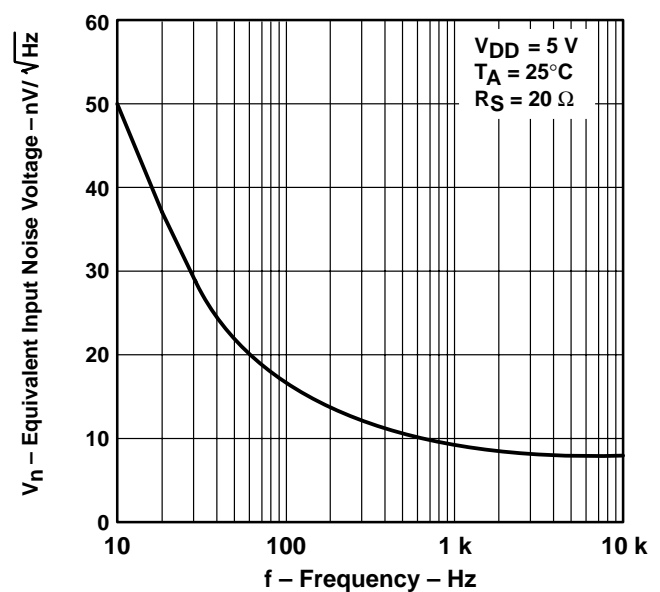


Figure 50

TYPICAL CHARACTERISTICS

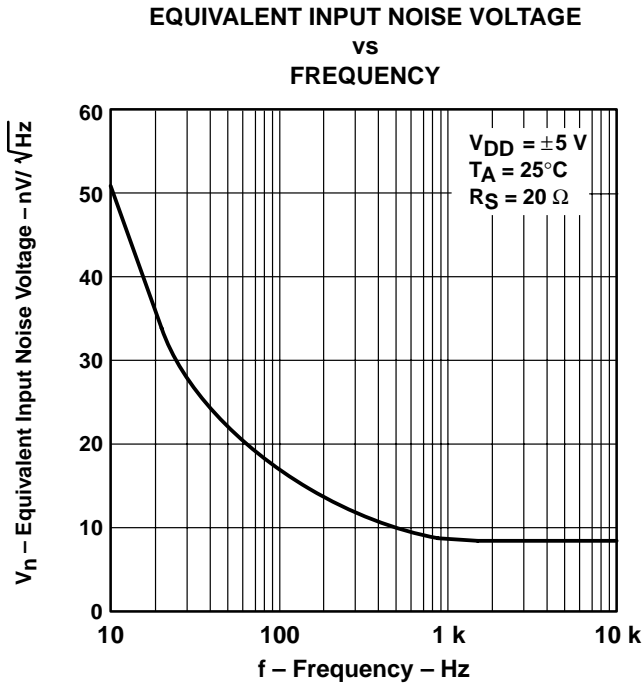


Figure 51

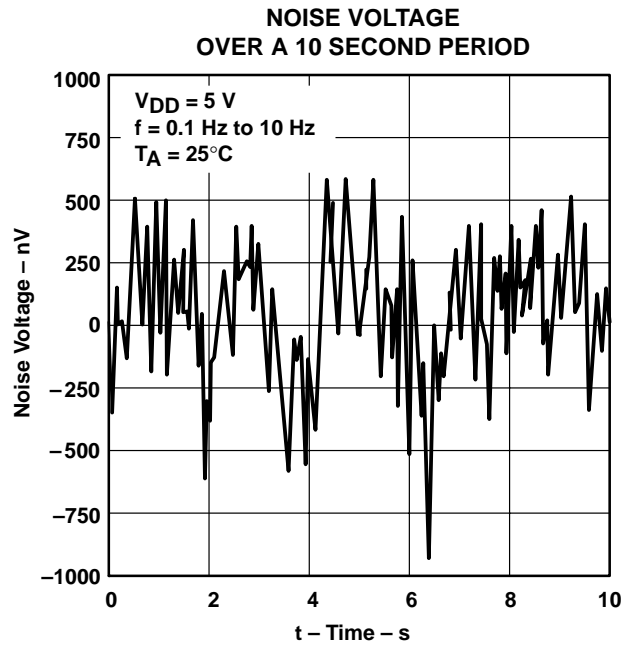


Figure 52

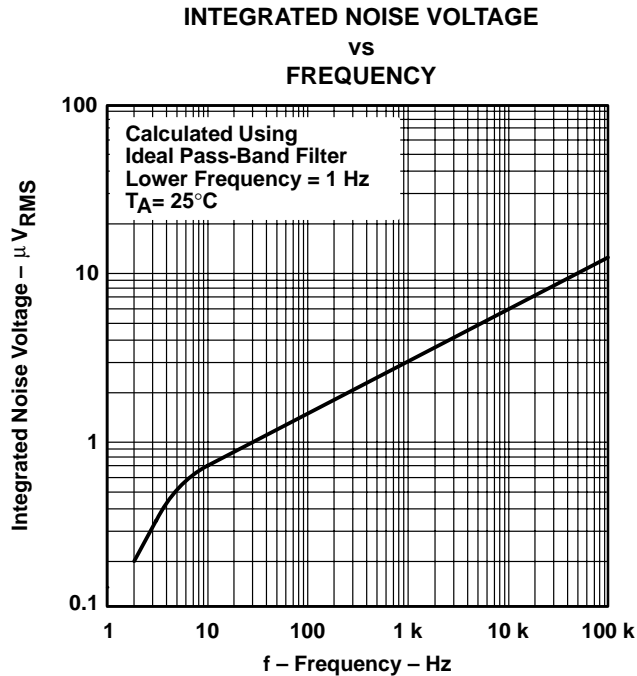


Figure 53

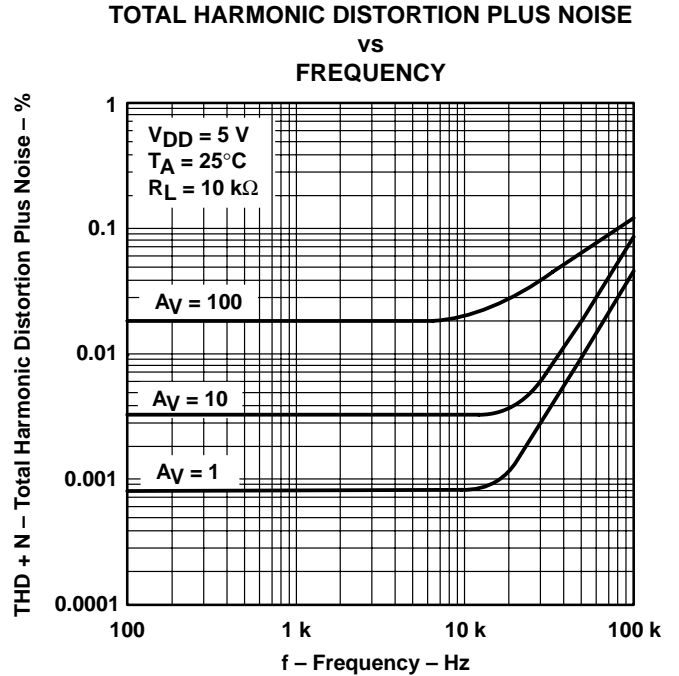


Figure 54

TYPICAL CHARACTERISTICS

GAIN-BANDWIDTH PRODUCT  
 vs  
 SUPPLY VOLTAGE

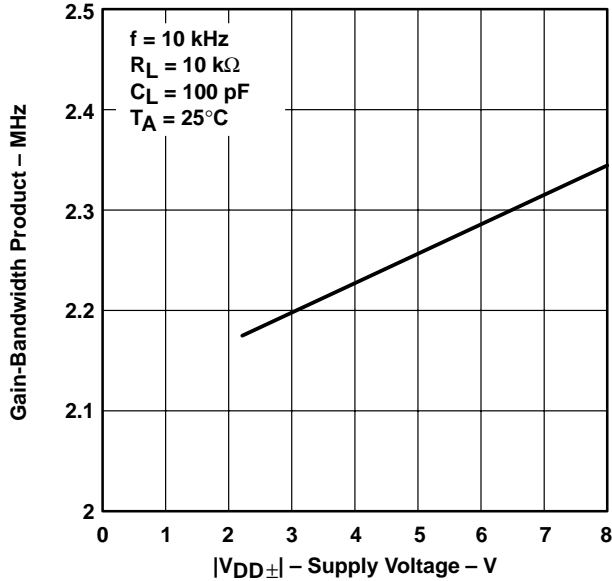


Figure 55

GAIN-BANDWIDTH PRODUCT†  
 vs  
 FREE-AIR TEMPERATURE

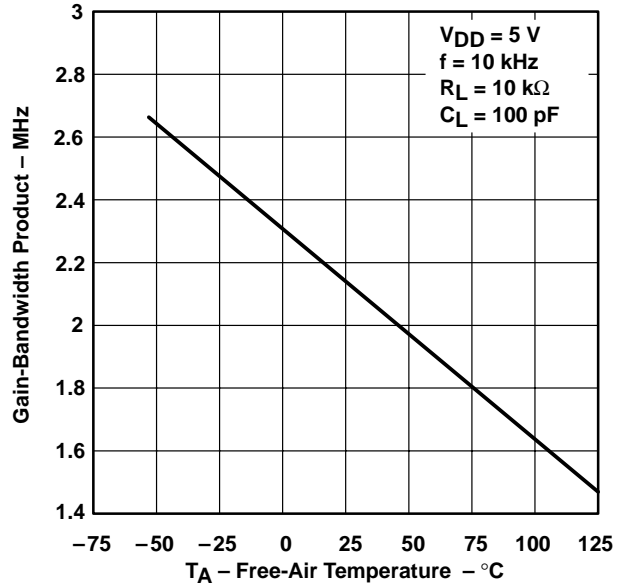


Figure 56

PHASE MARGIN  
 vs  
 LOAD CAPACITANCE

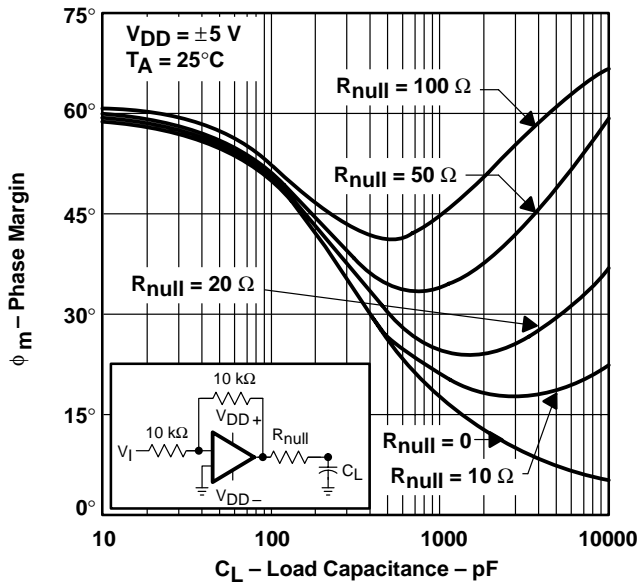


Figure 57

GAIN MARGIN  
 vs  
 LOAD CAPACITANCE

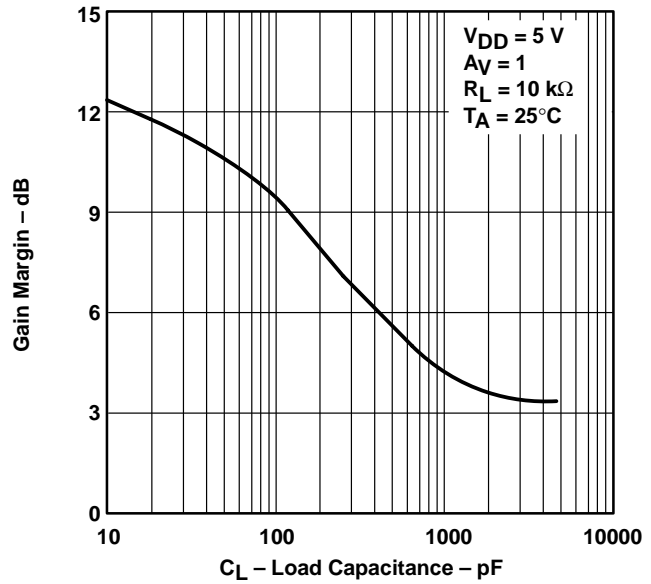


Figure 58

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 59 were generated using the TLC227x typical electrical and operating characteristics at T<sub>A</sub> = 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 5: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

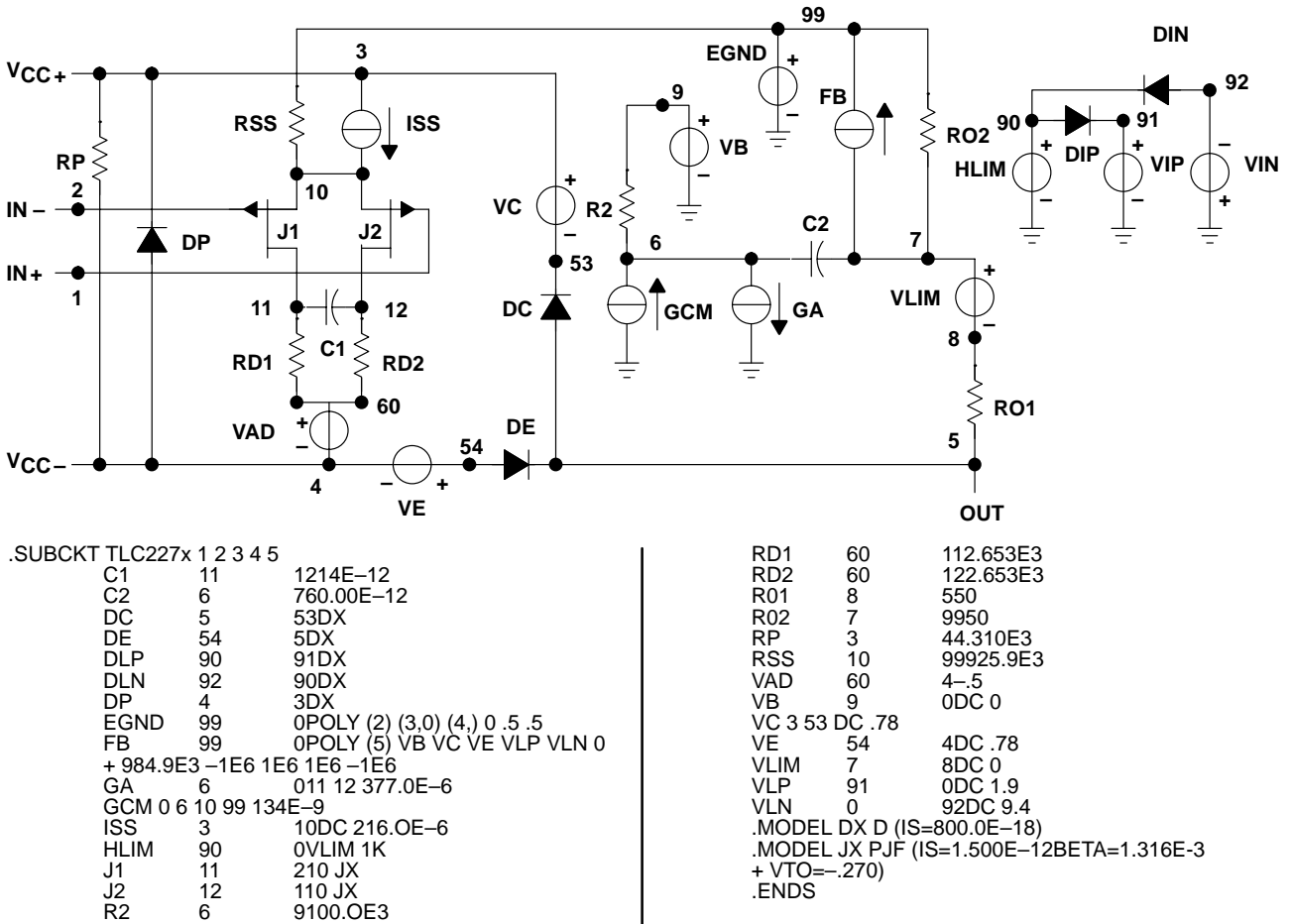


Figure 59. Boyle Macromodel and Subcircuit

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**TLC2272A-EP TLC2274A-EP**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**OPERATIONAL AMPLIFIERS**

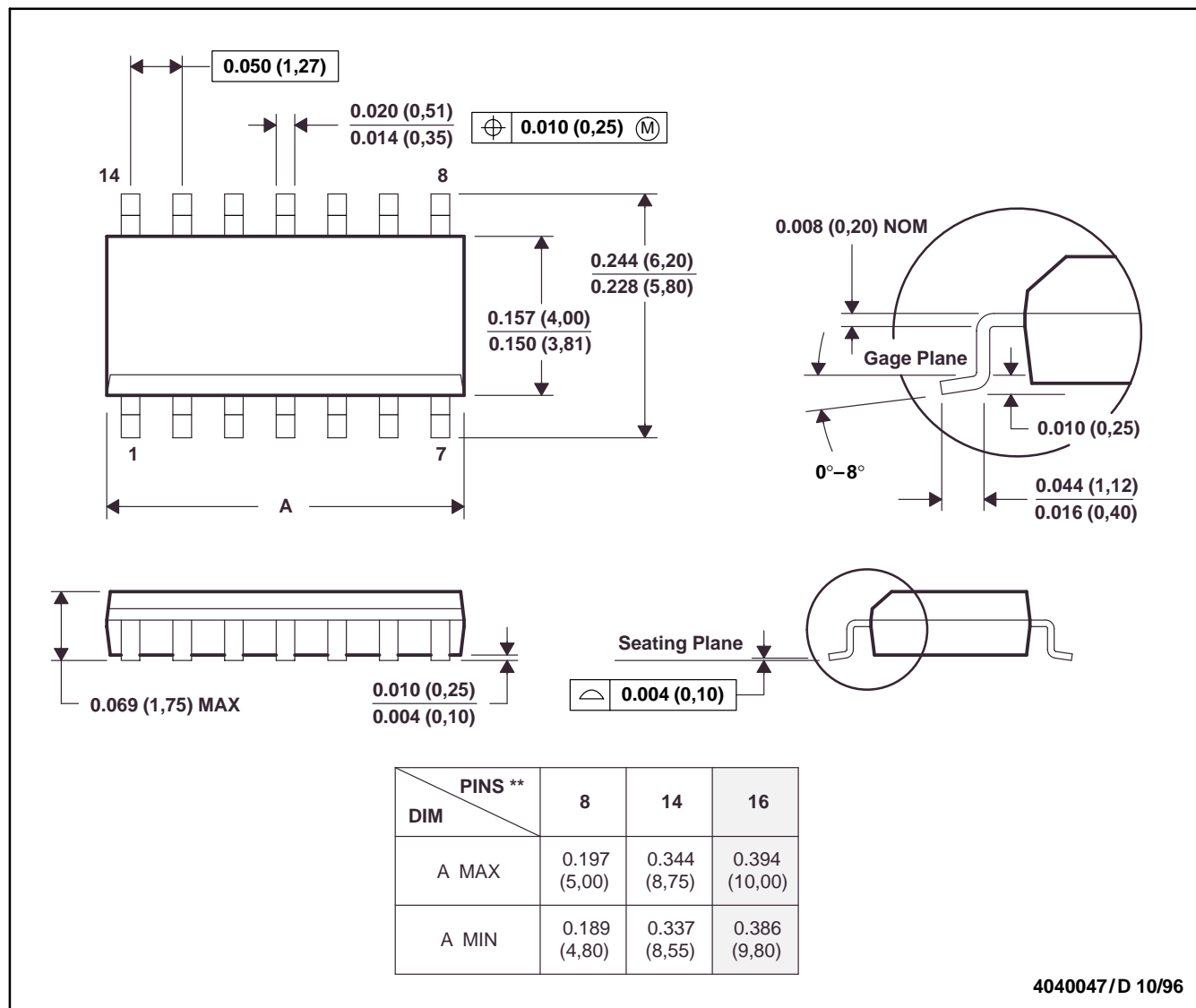
SGLS131 – JULY 2002

**MECHANICAL DATA**

**D (R-PDSO-G\*\*)**

**PLASTIC SMALL-OUTLINE PACKAGE**

14 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).  
 D. Falls within JEDEC MS-012

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